TEXAS INSTRUMENTS

# 具有 DCS-Control 的 TPS62147、TPS62148 高精度 3V 至 17V 2A 降压转换器

1 特性

- 额定 T_J 范围内的输出电压精度为 ±1%（PWM 模式）
- 输入电压范围：3V 至 17V
- 静态电流 18µA（典型值）
- 输出电压范围为 0.8V 至 12V
- 可调软启动
- 强制 PWM 或 PWM/PFM 操作
- 强制 PWM 模式中具有 1.25 MHz 或 2.5MHz 的开关频率
- 精密使能输入可实现
  - 用户定义的欠压锁定
  - 准确排序
- 100% 占空比模式
- 自动效率增强 (AEE)
- DCS-Control 拓扑
- 有源输出放电 (TPS62148)
- HICCUP 过流保护 (TPS62147)
- 电源正常状态输出
- 采用 2mm × 3mm VQFN 封装

2 应用

- 标准 12V 电源轨
- 移动和嵌入式计算机
- 多节电池组成的 POL 电源
- 工厂自动化、PLC、工业 PC
- 楼宇自动化、视频监控
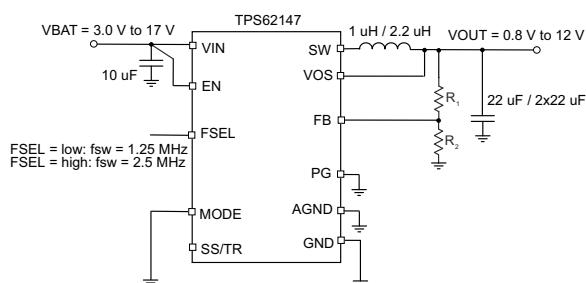
3 说明

TPS62147 和 TPS62148 是基于 DCS-Control 拓扑的高效且易于使用的同步直流/直流降压转换器。3V 至 17V 的宽输入电压范围使这些器件适用于多节锂离子电池以及 12V 中间电源轨。该器件提供 2A 连续输出电流。这些器件可在轻负载时自动进入节能模式，从而可在整个负载范围内保持高效率。因此，这些器件非常适合需要联网待机性能的应用，如工业 PC 和视频监控。MODE 引脚设置为低之后，器件会根据输出电流以及输入和输出电压自动调整开关频率。该技术称为自动效率增强 (AEE)，可在整个工作范围内保持高转换效率。TPS62147、TPS62148 可在 PWM 模式中提供 1% 的输出电压精度，因此可支持高输出电压精度的电源设计。FSEL 引脚允许在强制 PWM 模式中分别设置 1.25MHz 或 2.5MHz 的开关频率。

典型静态电流为 18µA。在关断模式中，典型电流为 1µA。

此器件提供了可调节版本，采用 3mm x 2mm VQFN 封装。

器件信息

器件型号[2]	封装[1]	封装尺寸（标称值）
TPS62147	RGX（VQFN，11）	3.00mm x 2.00mm
TPS62148		3.00mm x 2.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 请参阅 *Device Comparison Table*。

简化原理图
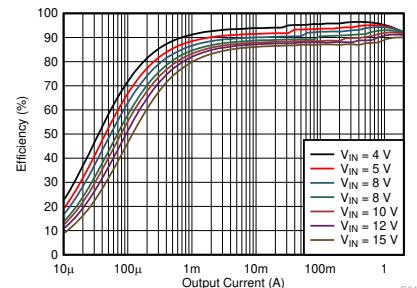
效率与输出电流间的关系，Vo = 3.3V；fsw = 1.25MHz；PFM

English Data Sheet: SLVSDR8

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

5 Device Comparison Table

| DEVICE NUMBER	FEATURES	OUTPUT VOLTAGE	MARKING
TPS62147	frequency selection on FSEL HICCUP current limit	adjustable	62147
TPS62148	frequency selection on FSEL output voltage discharge	adjustable	62148

6 Pin Configuration and Functions
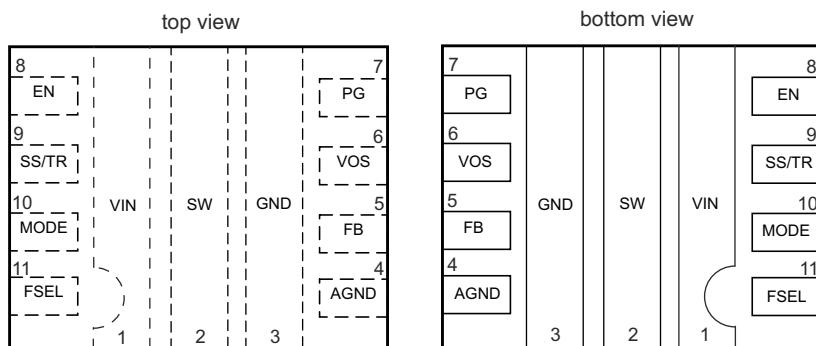
图 6-1. RGX Package 11-Pin VQFN

表 6-1. Pin Functions

PIN NUMBER	PIN NAME	I/O	DESCRIPTION
1	VIN	I	Power supply input. Make sure the input capacitor is connected as close as possible between pin VIN and GND.
2	SW		Switch pin of the converter connected to the internal Power MOSFETs.
3	GND	I	Ground pin.
4	AGND	I	Connect to GND.
5	FB	I	Voltage feedback input. Connect resistive output voltage divider to this pin.
6	VOS	I	Output voltage sense pin. Connect directly to the positive pin of the output capacitor.
7	PG	O	Open drain power good output. Leave open or tie to GND if not used.
8	EN	I	Enable pin of the device. Connect to logic low to disable the device. Pull high to enable the device. Do not leave this pin unconnected.
9	SS/TR	I	Soft-start / Tracking pin. An external capacitor connected from this pin to GND defines the rise time for the internal reference voltage. The pin can also be used as an input for tracking and sequencing - see *Detailed Description* section in this document.
10	MODE	I	The device runs in PFM/PWM mode when this pin is pulled low. When the pin is pulled high, the device runs in forced PWM mode. Do not leave this pin unconnected.
11	FSEL	I	Switching frequency setting pin. Pull to logic low for a switching frequency of 1.25 MHz. Pull to logic high for a switching frequency of 2.5 MHz. Do not leave FSEL unconnected.

7 Specifications

7.1 Absolute Maximum Ratings

Over junction temperature range of – 40°C to 150°C (unless otherwise noted)[1]

		MIN	MAX	UNIT
Pin voltage range[2]	VIN	– 0.3	20	V
	SW, VOS	– 0.3	V_{IN}+0.3	V
	SW (transient for t<10ns)[2]	– 2	25.5	V
	EN, MODE, FSEL, PG, FB, , SS/TR	– 0.3	V_{IN}+0.3	V
Operating junction temperature, T_J		– 40	150	°C
Storage temperature range, T_{stg}		– 65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the Recommended Operating Conditions but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) While switching

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human Body Model - (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±2000	V
		Charge Device Model - (CDM), per JEDEC specification JESD22-C101[2]	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
VIN	Supply voltage	3		17	V
VOUT	Output voltage	0.7		12	V
L	Effective inductance for fsw = 2.5 MHz	0.6	1	2.9	µH
L	Effective inductance for fsw = 1.25 MHz	0.7	1.5 or 2.2	2.9	µH
C_O	Effective output capacitance for fsw = 2.5 MHz[1]	6	22	200[3]	µF
C_O	Effective output capacitance for fsw = 1.25 MHz[1]	12	47	200[3]	µF
C_I	Effective input capacitance[1] [2]	3	10		µF
T_J	Operating junction temperature	– 40		125	°C

(1) The values given for all the capacitors are effective capacitance, which includes the dc bias effect. Please check the manufacturer´s dc bias curves for the effective capacitance vs dc bias voltage applied.
(2) Larger values can be required if the source impedance can not support the transient requirements of the load.
(3) This is for capacitors directly at the output of the device. More capacitance is allowed if there is a series resistance associated to the capacitors. See also the systems examples 节 10.3.2 for applications with many distributed capacitors on the output.

7.4 Thermal Information

THERMAL METRIC[1]		TPS62147, TPS62148	UNIT
		RGX (VQFN)	
		11 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	38.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	2.0	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	7.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	7.6	°C/W

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THERMAL METRIC[1]	TPS62147, TPS62148	UNIT
	RGX (VQFN)	
	11 PINS	
$R_{\theta JC(bot)}$ Junction-to-case (bottom) thermal resistance	3.2	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

7.5 Electrical Characteristics

$T_J = -40\ °C$ to $+125\ °C$ and $V_{IN} = 3\ V$ to $17\ V$. Typical values at $V_{IN} = 12\ V$ and $T_A = 25\ °C$, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
I_Q	Operating Quiescent Current	EN = high, I_{OUT}= 0 mA, Device not switching, T_J= 85 °C			35	µA
I_Q	Operating Quiescent Current	EN = high, I_{OUT}= 0 mA, Device not switching		18	46	µA
I_{SD}	Shutdown Current	EN = 0 V, Nominal value at T_J= 25 °C, Max value at T_J= 85 °C		1	8	µA
V_{UVLO}	Undervoltage Lockout Threshold	Rising Input Voltage	2.8	2.9	3.0	V
		Falling Input Voltage	2.5	2.6	2.7	V
T_{SD}	Thermal Shutdown Temperature	Rising Junction Temperature		160		°C
	Thermal Shutdown Hysteresis			20		
CONTROL (EN, SS/TR, PG, MODE, FSEL)						
V_{IH}	High Level Input Voltage for FSEL, MODE pin		0.9			V
V_{IL}	Low Level Input Voltage for FSEL, MODE pin				0.3	V
V_{IH}	Input Threshold Voltage for EN pin; rising edge		0.77	0.8	0.83	V
V_{IL}	Input Threshold Voltage for EN pin; falling edge		0.67	0.7	0.73	V
I_{LKG_EN}	Input Leakage Current for EN, FSEL, MODE	V_{IH} = VIN or V_{IL}= GND			100	nA
V_{TH_PG}	Power Good Threshold Voltage; dc level	Rising (%V_{OUT})	93%	96%	98%	
	Hysteresis	Falling (%V_{OUT})	3%		4.5%	
V_{OL_PG}	Power Good Output Low Voltage	I_{PG} = -2 mA		0.07	0.3	V
I_{LKG_PG}	Input Leakage Current (PG)	V_{PG} = 5 V			100	nA
$I_{SS/TR}$	SS/TR pin source current			2.5		µA
	$I_{SS/TR}$ tolerance	T_J= $-40\ °C$ to $+125\ °C$		±0.2		µA
	Tracking gain	V_{FB} / $V_{SS/TR}$		1		
	Tracking offset	feedback voltage with $V_{SS/TR}$ = 0 V		11		mV

7.5 Electrical Characteristics (continued)

T_J = – 40 °C to +125 °C and V_{IN} = 3 V to 17 V. Typical values at V_{IN} = 12 V and T_A = 25 °C, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
POWER SWITCH							
$R_{DS(ON)}$	High-Side MOSFET ON-Resistance	$V_{IN} \geqslant$ 4 V			100	180	mΩ
	Low-Side MOSFET ON-Resistance	$V_{IN} \geqslant$ 4 V			39	67	mΩ
I_{LIMH}	High-Side MOSFET Current Limit	dc value[2]		2.8	3.5	4.2	A
I_{LIML}	Low-Side MOSFET Current Limit	dc value[2]		2.8	3.5	4.2	A
I_{LIMNEG}	Negative current limit; average value	dc value			1.5		A
OUTPUT							
V_{FB}	Feedback Voltage				0.7		V
I_{LKG_FB}	Input Leakage Current (FB)	V_{FB}= 0.7 V			1	70	nA
V_{FB}	Feedback Voltage Accuracy[1]	$V_{IN} \geqslant V_{OUT}$ +1 V	PWM mode	-1%		1%	
		$V_{IN} \geqslant V_{OUT}$ +1 V; $V_{OUT} \geqslant$ 1.5 V	PFM mode; Co,eff $\geqslant$ 47 µF, L = 1 µH for FSEL = high, L = 1.5 µH for FSEL = low	-1%		2%	
		1 V $\leqslant V_{OUT}$ < 1.5 V	PFM mode; Co,eff $\geqslant$ 47 µF, L = 1 µH for FSEL = high, Co,eff $\geqslant$ 60 µF, L = 1.5 µH for FSEL = low	-1%		2.5%	
		V_{OUT} < 1 V	PFM mode; Co,eff $\geqslant$ 75 µF, L = 1 µH for FSEL = high, L = 1.5 µH for FSEL = low	-1%		2.5%	
V_{FB}	Feedback Voltage Accuracy with Voltage Tracking	$V_{IN} \geqslant V_{OUT}$ +1 V; $V_{SS/TR}$ = 0.35 V	PWM mode	-2%		7.5%	
	Load Regulation	PWM mode operation			0.05		%/A
	Line Regulation	PWM mode operation, I_{OUT}= 1 A, VIN $\geqslant$ Vout + 1 V or VIN $\geqslant$ 3.5 V whichever is larger			0.02		%/V
	Output Discharge Resistance				100		Ω
t_{delay}	Start-up Delay time	I_O= 0 mA, Time from EN=high to start switching; VIN applied already			200	300	µs
t_{ramp}	Ramp time; SS/TR pin open	I_O= 0 mA, Time from first switching pulse until 95% of nominal output voltage; device not in current limit			150		µs

(1) The output voltage accuracy in Power Save Mode can be improved by increasing the output capacitor value, reducing the output voltage ripple (see *Pulse Width Modulation (PWM) Operation*).

(2) See also 节 *9.4.5*.

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

7.6 Typical Characteristics
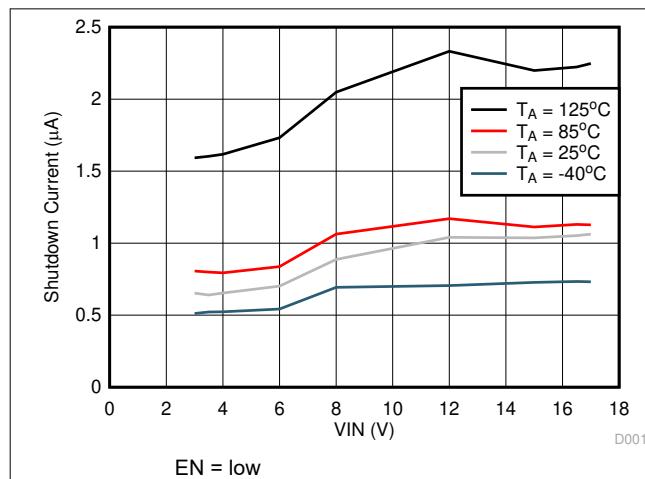
图 7-1. Shutdown Current vs Input Voltage
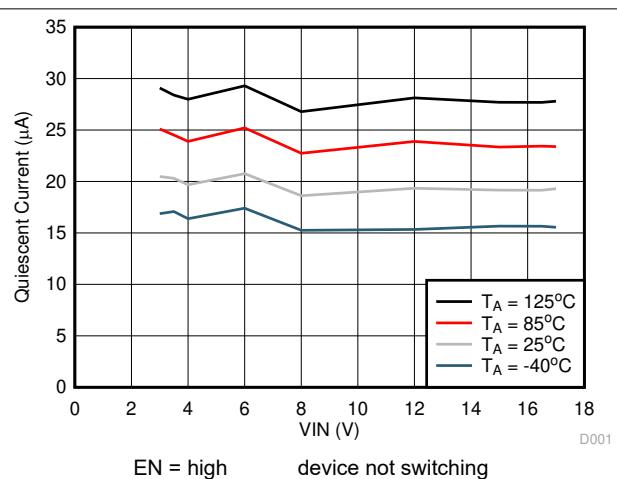
图 7-2. Quiescent Supply Current vs Input Voltage

8 Parameter Measurement Information

8.1 Schematic
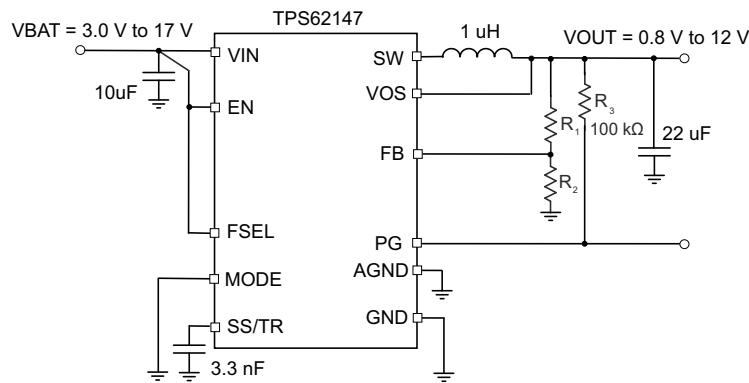
图 8-1. Measurement Setup with FSEL = high

表 8-1. List of Components for FSEL = high (fsw = 2.5 MHz)

REFERENCE	DESCRIPTION	MANUFACTURER
IC	17 V, 2 A Step-Down Converter	TPS62147; Texas Instruments
L	1 µH inductor	XFL4020-102; Coilcraft
CIN	10 µF, 25 V, Ceramic, 0805	TMK212BBJ106MG-T; Taiyo Yuden
COUT	2 × 10 µF, 16 V, Ceramic, 0805; all VOUT except 9 V and 1.2 V	EMK212BBJ106MG-T; Taiyo Yuden
COUT	3 × 10 µF, 16 V, Ceramic, 0805 for VOUT = 1.2 V	EMK212BBJ106MG-T; Taiyo Yuden
COUT	4 × 10 µF, 16 V, Ceramic, 0805 for VOUT = 9 V	EMK212BBJ106MG-T; Taiyo Yuden
CSS	3.3 nF, 10 V, Ceramic, X7R	-
R1	Depending on Vout; see 表 10-4	Standard 1% metal film
R2	Depending on Vout; see 表 10-4	Standard 1% metal film
R3	470 kΩ, Chip, 0603, 1/16 W, 1%	Standard 1% metal film

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: SLVSDR8
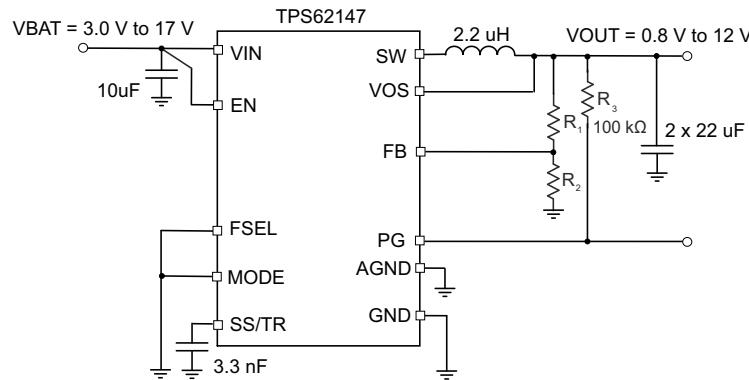
图 8-2. **Measurement Setup with FSEL = low**

表 8-2. **List of Components for FSEL = low (fsw = 1.25 MHz)**

REFERENCE	DESCRIPTION	MANUFACTURER[1]
IC	17 V, 2 A Step-Down Converter	TPS62147; Texas Instruments
L	2.2 µH inductor	XFL4020-222; Coilcraft
CIN	10 µF, 25 V, Ceramic, 0805	TMK212BBJ226MG-T; Taiyo Yuden
COUT	2 × 22 µF, 16 V, Ceramic, 0805; all VOUT except 9 V and 1.2 V	EMK212BBJ226MG-T; Taiyo Yuden
COUT	3 × 22 µF, 16 V, Ceramic, 0805 for VOUT = 1.2 V and VOUT = 9 V	EMK212BBJ226MG-T; Taiyo Yuden
CSS	3.3 nF, 10 V, Ceramic, X7R	-
R1	Depending on Vout; see 表 10-4	Standard 1% metal film
R2	Depending on Vout; see 表 10-4	Standard 1% metal film
R3	470 kΩ, Chip, 0603, 1/16 W, 1%	Standard 1% metal film

(1)　　See *Third-party Products Disclaimer*

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English Data Sheet: *SLVSDR8*

9 Detailed Description

9.1 Overview

The TPS62147, TPS62148 synchronous switched mode power converters are based on DCS-Control (Direct Control with Seamless Transition into Power Save Mode), an advanced regulation topology that combines the advantages of hysteretic, voltage mode and current mode control. This control loop takes information about output voltage changes and feeds it directly to a fast comparator stage. It sets the switching frequency, which is constant for steady state operating conditions, and provides immediate response to dynamic load changes. To get accurate dc load regulation, a voltage feedback loop is used. The internally compensated regulation network achieves fast and stable operation with small external components and low ESR capacitors.

The DCS-Control topology supports PWM (Pulse Width Modulation) mode for medium and heavy load conditions and a Power Save Mode at light loads. During PWM, it operates at its nominal switching frequency in continuous conduction mode. This frequency is typically about 1.25 MHz or 2.5 MHz, depending on the setting of the FSEL pin, with a controlled frequency variation depending on the input voltage. If the load current decreases, the converter enters Power Save Mode to sustain high efficiency down to very light loads. In Power Save Mode the switching frequency decreases linearly with the load current. Because DCS-Control supports both operation modes within one single building block, the transition from PWM to Power Save Mode is seamless. An internal current limit supports nominal output currents of up to 2 A. The TPS62147, TPS62148 offer both excellent dc voltage and superior load transient regulation, combined with very low output voltage ripple, minimizing interference with RF circuits.

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9.2 Functional Block Diagram
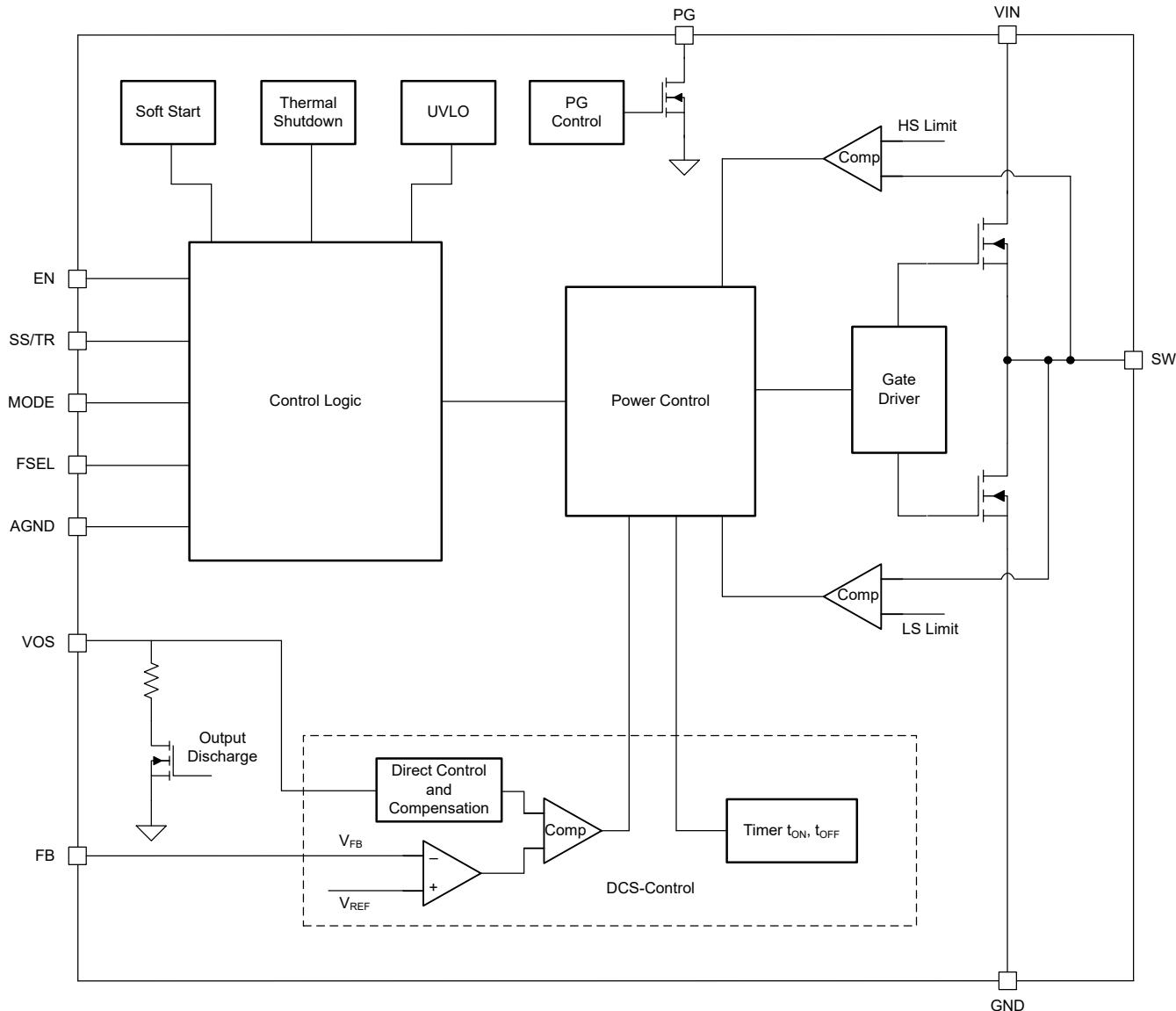
The discharge switch on the VOS pin is not available in the TPS62147.

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: SLVSDR8

9.3 Feature Description

9.3.1 Precise Enable

The voltage applied at the Enable pin of the TPS62147, TPS62148 is compared to a fixed threshold of 0.8 V for a rising voltage. This allows to drive the pin by a slowly changing voltage and enables the use of an external RC network to achieve a power-up delay.

The Precise Enable input allows the use as a user programmable undervoltage lockout by adding a resistor divider to the input of the Enable pin.

The enable input threshold for a falling edge is typically 100 mV lower than the rising edge threshold. The TPS62147, TPS62148 start operation when the rising threshold is exceeded. For proper operation, the EN pin must be terminated and must not be left floating. Pulling the EN pin low forces the device into shutdown, with a shutdown current of typically 1 μA. In this mode, the internal high side and low side MOSFETs are turned off and the entire internal control circuitry is switched off.

9.3.2 Power Good (PG)

The built-in power good (PG) function indicates whether the output voltage has reached its target. The PG signal can be used for startup sequencing of multiple rails. The PG pin is an open-drain output that requires a pull-up resistor to any voltage up to a voltage level of the input voltage at VIN. It can sink 2 mA of current and maintain its specified logic low level. PG is low when the device is turned off due to EN, UVLO or thermal shutdown, so it can be used to actively discharge Vout. VIN must remain present for the PG pin to stay low.

The power good threshold in transient operation can be slightly different from the dc values given in the electrical specification in case a feed forward capacitor is used on the output voltage divider. Due to the capacitive coupling, power good can go high for a short time after a release of a short circuit on the output.

If the power good output is not used, it is recommended to tie to GND or leave open.

9.3.3 MODE

When MODE is set low, the device operates in PWM or PFM mode depending on the output current. Automatic Efficiency Enhancement (AEE), which scales the switching frequency based on the input voltage and the output voltage, is enabled for highest efficiency over a wide input voltage, output voltage and output current range. The MODE pin allows to force PWM mode when set high. In forced PWM mode, AEE is disabled. See also *Power Save Mode Operation (PWM/PFM)*.

9.3.4 Undervoltage Lockout (UVLO)

If the input voltage drops, the undervoltage lockout prevents mis-operation of the device by switching off both the power FETs. The device is fully operational for voltages above the rising UVLO threshold and turns off if the input voltage trips below the threshold for a falling supply voltage.

9.3.5 Thermal Shutdown

The junction temperature (T_J) of the device is monitored by an internal temperature sensor. If T_J exceeds 160°C (typ), the device goes into thermal shutdown. Both the high-side and low-side power FETs are turned off and PG goes low. When T_J decreases below the hysteresis amount of typically 20°C, the converter resumes normal operation, beginning with soft-start. During a PFM skip pause, the thermal shutdown is not active. See also *Power Save Mode Operation (PWM/PFM)*.

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English Data Sheet: *SLVSDR8*

9.4 Device Functional Modes

9.4.1 Pulse Width Modulation (PWM) Operation

TPS62147, TPS62148 have two operating modes: Forced PWM mode discussed in this section and PWM/PFM as discussed in *Power Save Mode Operation (PWM/PFM)*.

With the MODE pin set to high, the TPS62147, TPS62148 operate with pulse width modulation in continuous conduction mode (CCM) with a nominal switching frequency of 2.5 MHz for FSEL = high and 1.25 MHz for FSEL = low. The frequency variation in PWM is controlled and depends on VIN, VOUT and the inductance. The on-time (TON) in forced PWM mode depends on the setting of FSEL.

For FSEL = high (2.5 MHz):

$$TON = \frac{VOUT}{VIN} \times 400 \, [ns]$$

(1)

For FSEL = low (1.25 MHz):

$$TON = \frac{VOUT}{VIN} \times 800 \, [ns]$$

(2)

9.4.2 Power Save Mode Operation (PWM/PFM)

When the MODE pin is low, Power Save Mode is allowed. The device operates in PWM mode as long the output current is higher than half the inductor ripple current. To maintain high efficiency at light loads, the device enters Power Save Mode at the boundary to discontinuous conduction mode (DCM). This happens if the output current becomes smaller than half the inductor ripple current. For improved transient response, PWM mode is forced for 8 switching cycles if the output voltage is above target due to a load release. The Power Save Mode is entered seamlessly, if the load current decreases and the MODE pin is set low. This ensures a high efficiency in light load operation. The device remains in Power Save Mode as long as the inductor current is discontinuous.

In Power Save Mode the switching frequency decreases linearly with the load current maintaining high efficiency. The transition into and out of Power Save Mode is seamless in both directions.

The AEE function in TPS62147, TPS62148 adjusts the on-time (TON) in power save mode depending on the input voltage and the output voltage to maintain highest efficiency. The on-time, in steady-state operation, can be estimated as follows.

For FSEL = high (2.5MHz):

$$TON = 100 \times \frac{VIN}{VIN - VOUT} \, [ns]$$

(3)

For FSEL = low (1.25MHz):

$$TON = 200 \times \frac{VIN}{VIN - VOUT} \, [ns]$$

(4)

For very small output voltages, an absolute minimum on-time of about 50 ns is kept to limit switching losses. The operating frequency is thereby reduced from its nominal value, which keeps efficiency high. Using TON, the typical peak inductor current in Power Save Mode is approximated by:

$$ILPSM_{(peak)} = \frac{(VIN - VOUT)}{L} \times TON$$

(5)

Product Folder Links: *TPS62147 TPS62148*

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There is a minimum off-time which limits the duty cycle of the TPS62147, TPS62148. When VIN decreases to typically 15% above VOUT, the TPS62147, TPS62148 does not enter Power Save Mode, regardless of the load current. The device maintains output regulation in PWM mode.

The output voltage ripple in power save mode is given by 方程式 6:

$$\Delta V = \frac{L \times VIN^2}{200 \times C}\left(\frac{1}{VIN - VOUT} + \frac{1}{VOUT}\right) \tag{6}$$

9.4.3 100% Duty-Cycle Operation

The duty cycle of the buck converter is given by D = VOUT / VIN and increases as the input voltage comes close to the output voltage. The minimum off-time is about 80 ns. When the minimum off-time is reached, TPS62147, TPS62148 scale down the switching frequency while they approach 100% mode. In 100% mode the high-side switch is on continuously. The high-side switch stays turned on as long as the output voltage is below the internal set point. This allows the conversion of small input to output voltage differences, for example for longest operation time of battery-powered applications. In 100% duty-cycle mode, the low-side FET is switched off.

The minimum input voltage to maintain output voltage regulation, depending on the load current and the output voltage level, can be calculated as:

$$VIN_{(min)} = VOUT + IOUT\left(R_{DS(on)} + R_L\right) \tag{7}$$

where

- IOUT is the output current,
- $R_{DS(on)}$ is the on-state resistance of the high-side FET and
- R_L is the dc resistance of the inductor used.

9.4.4 Current Limit And Short Circuit Protection (for TPS62148)

The TPS62148 is protected against overload and short circuit events. If the inductor current exceeds the current limit I(LIMF), the high side switch is turned off and the low side switch is turned on to ramp down the inductor current. This allows it to provide the maximum current, for example, charging a large output capacitance without the must increase the soft-start time.

Due to internal propagation delay, the actual current can exceed the static current limit during that time. The dynamic current limit is given as:

$$I_{peak(typ)} = I_{LIMH} + \frac{V_L}{L} \times t_{PD} \tag{8}$$

where

- I_{LIMF} is the static current limit as specified in the electrical characteristics
- L is the effective inductance at the peak current
- V_L is the voltage across the inductor (V_{IN} - V_{OUT}) and
- t_{PD} is the internal propagation delay of typically 50 ns.

The current limit can exceed static values, especially if the input voltage is high and very small inductances are used. The dynamic high side switch peak current can be calculated as follows:

$$I_{peak(typ)} = I_{LIMH} + \frac{VIN - VOUT}{L} \times 50ns \tag{9}$$

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

9.4.5 HICCUP Current Limit And Short Circuit Protection (for TPS62147)

The TPS62147 is protected against overload and short circuit events. If the inductor current exceeds the current limit I(LIMF), the high side switch is turned off and the low side switch is turned on to ramp down the inductor current. After the switch current limit is triggered for 512 switching cycles, the device stops switching. After a typical delay of 800 µs, the device begins a new soft-start cycle. This is called HICCUP short circuit protection. TPS62147 repeats this mode until the short circuit condition disappears.

Due to internal propagation delay, the actual current can exceed the static current limit during that time. The equations given under *Current Limit And Short Circuit Protection (for TPS62148)* also apply.

9.4.6 Soft Start / Tracking (SS/TR)

The internal soft-start circuitry controls the output voltage slope during startup. This avoids excessive inrush current and ensures a controlled output voltage rise time. It also prevents unwanted voltage drops from high impedance power sources or batteries. When EN is set high to start operation, the device starts switching after a delay of about 200 µs then the internal reference and hence VOUT rises with a slope controlled by an external capacitor connected to the SS/TR pin.

Leaving SS/TR pin unconnected provides fastest startup ramp with 150 µs typically.

If the device is set to shutdown (EN = GND), undervoltage lockout or thermal shutdown, an internal resistor pulls the SS/TR pin down to ensure a proper low level. Returning from those states causes a new startup sequence as set by the SS/TR connection.

A voltage supplied to SS/TR can be used to track a master voltage. The output voltage follows this voltage in both directions up and down in forced PWM mode. In PFM mode, the output voltage decreases based on the load current. The SS/TR pin of several devices must not be connected with each other.

9.4.7 Output Discharge Function (TPS62148 only)

The purpose of the discharge function is to ensure a defined down-ramp of the output voltage when the device is being disabled but also to keep the output voltage close to 0 V when the device is off. The output discharge feature is only active once TPS62148 has been enabled at least once since the supply voltage was applied. The internal discharge resistor is connected to the VOS pin. The discharge function is enabled as soon as the device is disabled, in thermal shutdown or in undervoltage lockout. The minimum supply voltage required for the discharge function to remain active typically is 2 V.

9.4.8 Starting into a Pre-Biased Load

The TPS62147 is capable of starting into a pre-biased output. The device only starts switching when the internal soft-start ramp is equal or higher than the feedback voltage. If the voltage at the feedback pin is biased to a higher voltage than the nominal value, the TPS62147 does not start switching unless the voltage at the feedback pin drops to the target.

This functionality actually also applies to TPS62148 but the discharge function in TPS62148 keeps the voltage close to 0 V, so starting into a pre-biased output does not apply.

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

10 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

10.1 Application Information

10.1.1 Programming the Output Voltage

The output voltage is adjustable. It can be programmed for output voltages from 0.8 V to 12 V, using a resistor divider from VOUT to GND. The voltage at the FB pin is regulated to 0.7 V. The value of the output voltage is set by the selection of the resistor divider from 方程式 10. It is recommended to choose resistor values which allow a current of at least 2 uA, meaning the value of R2 must not exceed 400 kΩ. Lower resistor values are recommended for highest accuracy and most robust design.

$$R_1 = R_{2 \times} \left(\frac{VOUT}{VFB} - 1 \right)$$

(10)

10.1.2 External Component Selection

The external components have to fulfill the needs of the application, but also the stability criteria of the device´s control loop. The TPS62147, TPS62148 are optimized to work within a range of external components. The LC output filters inductance and capacitance have to be considered together, creating a double pole, responsible for the corner frequency of the converter (see *Output Filter and Loop Stability*). 表 10-1 can be used to simplify the output filter component selection.

表 10-1. Recommended LC Output Filter Combinations[1]

	4.7 µF	10 µF	22 µF	47 µF	100 µF	200 µF	≥ 400 µF
0.68 µH		√	√	√			
1 µH		√	√[2]	√	√	√	√[4]
1.5 µH		√	√	√	√	√	√[4]
2.2 µH		√	√	√[3]	√	√	√[4]
3.3 µH							

(1) The values in the table are nominal values.
(2) This LC combination is the standard value and recommended for most applications with FSEL = high.
(3) This LC combination is the standard value and recommended for most applications with FSEL = low.
(4) Output capacitance must have a ESR of ≥ 10 mΩ for stable operation, see also *Powering Multiple Loads*.

10.1.3 Inductor Selection

The TPS62147, TPS62148 are designed for a nominal 1-µH inductor if FSEL = high and a 1.5-uH or 2.2-uH inductor if FSEL = low. Larger values can be used to achieve a lower inductor current ripple but they can have a negative impact on efficiency and transient response. Smaller values than 1 µH cause a larger inductor current ripple which causes larger negative inductor current in forced PWM mode at low or no output current. Therefore they are not recommended at large voltages across the inductor as it is the case for high input voltages and low output voltages. With low output current in forced PWM mode this causes a larger negative inductor current peak which can exceed the negative current limit.

The inductor selection is affected by several effects like inductor ripple current, output ripple voltage, PWM-to-PFM transition point and efficiency. In addition, the inductor selected has to be rated for appropriate saturation current and dc resistance (DCR). 方程式 11 calculates the maximum inductor current.

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$$I_{L(\text{max})} = I_{OUT(\text{max})} + \frac{\Delta I_{L(\text{max})}}{2}$$

(11)

$$\Delta I_{L(\text{max})} = \frac{VIN_{(\text{max})}}{L_{(\text{min})}} \times 100ns$$

(12)

where

- $I_L(\text{max})$ is the maximum inductor current
- $\triangle I_L$ is the Peak to Peak Inductor Ripple Current
- $L(\text{min})$ is the minimum effective inductor value.

Above equation is valid for FSEL = high. With FSEL = low, the ON-time is doubled from 100 ns to 200 ns so the peak inductor current doubles given the same input voltage and inductor.

Calculating the maximum inductor current using the actual operating conditions gives the minimum saturation current of the inductor needed. A margin of about 20% is recommended to add. A larger inductor value is also useful to get lower ripple current, but increases the transient response time and size as well. The following inductors have been used with the TPS62147, TPS62148 and are recommended for use:

表 **10-2. List of Inductors**[1]

TYPE	INDUCTANCE [µH]	CURRENT [A][2]	DIMENSIONS [LxBxH] mm	MANUFACTURER[1]
XFL3012-102ME	1.0 µH, ±20%	2.3	3 x 3 x 1.3	Coilcraft
XFL4015-122ME	1.2µH, ±20%	4.5	4 x 4 x 1.6	Coilcraft
XFL4020-102ME	1.0 µH, ±20%	5.4	4 × 4 x 2.1	Coilcraft
XFL4020-152ME	1.5 µH, ±20%	4.6	4 x 4 x 2.1	Coilcraft
XFL4020-222ME	2.2 µH, ±20%	3.7	4 x 4 x 2.1	Coilcraft
DFE322512F-2R2M	2.2 µH, ±20%	2.6	3.2 x 2.5 x 1.2	Murata
DFE322512F-1R5M	1.5 µH, ±20%	3.0	3.2 x 2.5 x 1.2	Murata
DFE322512F-1R0M	1.0 µH, ±20%	3.8	3.2 x 2.5 x 1.2	Murata

(1) See *Third-Party Products Disclaimer*
(2) Lower of I_{RMS} at 40°C rise or I_{SAT} at 30% drop.

The inductor value also determines the load current at which Power Save Mode is entered:

$$I_{load(PSM)} = \frac{1}{2}\Delta I_L$$

(13)

10.1.4 Capacitor Selection

10.1.4.1 Output Capacitor

The recommended value for the output capacitor is 22 µF with FSEL = high (fsw = 2.5 MHz) and 2 x 22 µF with FSEL = low (fsw = 1.25 MHz). The architecture of the TPS62147, TPS62148 allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, it is recommended to use X7R or X5R dielectric. Using a higher value has advantages like smaller voltage ripple and a tighter dc output accuracy in Power Save Mode.

In Power Save Mode, the output voltage ripple depends on the output capacitance, its ESR, ESL and the peak inductor current. Using ceramic capacitors provides small ESR, ESL and low ripple. The output capacitor must be as close as possible to the device.

For large output voltages the dc bias effect of ceramic capacitors is large and the effective capacitance has to be observed.

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

10.1.4.2 Input Capacitor

For most applications, 10 µF nominal is sufficient and is recommended, though a larger value reduces input current ripple further. The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. A low ESR multilayer ceramic capacitor (MLCC) is recommended for best filtering and must be placed between VIN and GND as close as possible to those pins.

表 10-3. List of Capacitors[1]

TYPE	NOMINAL CAPACITANCE [µF]	VOLTAGE RATING [V]	SIZE	MANUFACTURER[1]
TMK212BBJ106MG-T	10	25	0805	Taiyo Yuden
EMK212BBJ226MG-T	22	16	0805	Taiyo Yuden

(1)   See *Third-Party Products Disclaimer*

10.1.4.3 Soft-Start Capacitor

A capacitor connected between SS/TR pin and GND sets user programmable start-up slope of the output voltage. A constant current source provides typically 2.5 µA to charge the external capacitance. The capacitor required for a given soft-start ramp time is given by:

$$C_{SS} = t_{SS} \times \frac{2.5 \mu A}{0.7V} \ [F]$$

(14)

where

- C_{SS} is the capacitance required at the SS/TR pin and
- t_{SS} is the desired soft-start ramp time

The fastest achievable typical ramp time is 150 µs even if the external C_{ss} capacitance is lower than 680 pF or the pin is open.

10.1.5 Tracking Function

If a tracking function is desired, the SS/TR pin can be used for this purpose by connecting it to an external tracking voltage. The output voltage tracks that voltage with the typical gain and offset as specified in the electrical characteristics.

$$V_{FB} \approx V_{SS/TR}$$

(15)

When the SS/TR pin voltage is above 0.7 V, the internal voltage is clamped and the device goes to normal regulation. This works for rising and falling tracking voltages with the same behavior, as long as the input voltage is inside the recommended operating conditions. For decreasing SS/TR pin voltage in PFM mode, the device does not sink current from the output. The resulting decrease of the output voltage can therefore be slower than the SS/TR pin voltage if the load is light. When driving the SS/TR pin with an external voltage, do not exceed the voltage rating of the SS/TR pin which is V_{IN} + 0.3 V. The SS/TR pin is internally connected with a resistor to GND when EN = 0.

If the input voltage drops below undervoltage lockout, the output voltage goes to zero, independent of the tracking voltage. 图 10-1 shows how to connect devices to get ratiometric and simultaneous sequencing by using the tracking function. See also 节 10.3.3 in the systems examples. SS/TR is internally clamped to approximately 3 V.

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*
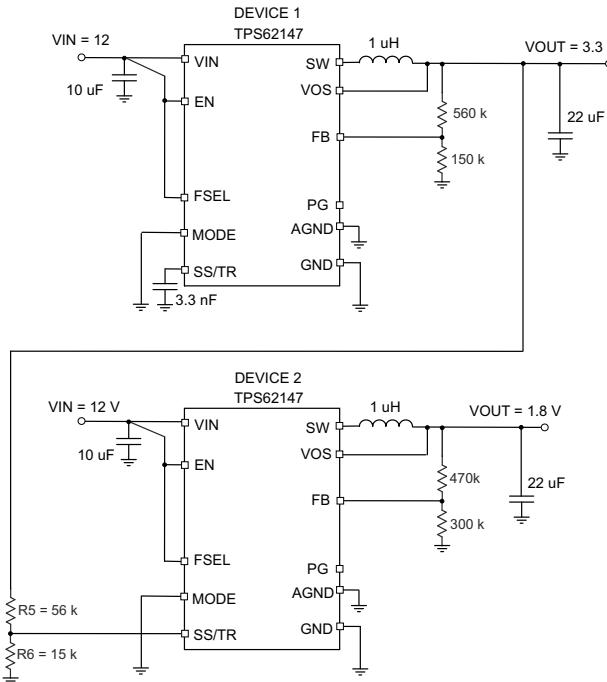
图 **10-1. Schematic for Ratiometric and Simultaneous Startup**

The resistive divider of R5 and R6 can be used to change the ramp rate of VOUT2 to be faster, slower or the same as VOUT1.

A sequential startup is achieved by connecting the PG pin of VOUT of DEVICE 1 to the EN pin of DEVICE2. PG requires a pull-up resistor. Ratiometric start up sequence happens if both supplies are sharing the same soft-start capacitor. 方程式 14 gives the soft-start time, though the SS/TR current has to be doubled.

Note: If the voltage at the FB pin is below its typical value of 0.7 V, the output voltage accuracy can have a wider tolerance than specified. The current of 2.5 μA out of the SS/TR pin also has an influence on the tracking function, especially for high resistive external voltage dividers on the SS/TR pin.

10.1.6 Output Filter and Loop Stability

The TPS62147, TPS62148 are internally compensated to be stable with L-C filter combinations corresponding to a corner frequency to be calculated with 方程式 16:

$$f_{LC} = \frac{1}{2\pi \sqrt{L \cdot C}}$$

(16)

Proven nominal values for inductance and ceramic capacitance are given in 表 10-1 and are recommended for use. Different values can work, but care has to be taken for the loop stability which is affected.

The TPS62147, TPS62148 include an internal 15 pF feedforward capacitor, connected between the VOS and FB pins. This capacitor impacts the frequency behavior and sets a pole and zero in the control loop with the resistors of the feedback divider, per equation 方程式 17 and 方程式 18:

$$f_{zero} = \frac{1}{2\pi \times R_1 \times 15\,pF}$$

(17)

$$f_{pole} = \frac{1}{2\pi \times 15\,pF}\left(\frac{1}{R_1} + \frac{1}{R_2}\right)$$

(18)

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Though the TPS62147, TPS62148 are stable without the pole and zero being in a particular location, adjusting their location to the specific needs of the application can provide better performance in Power Save mode and/or improved transient response. An external feedforward capacitor can also be added. A more detailed discussion on the optimization for stability versus transient response can be found in SLVA289 and SLVA466.

10.2 Typical Applications

10.2.1 Typical Application with Adjustable Output Voltage
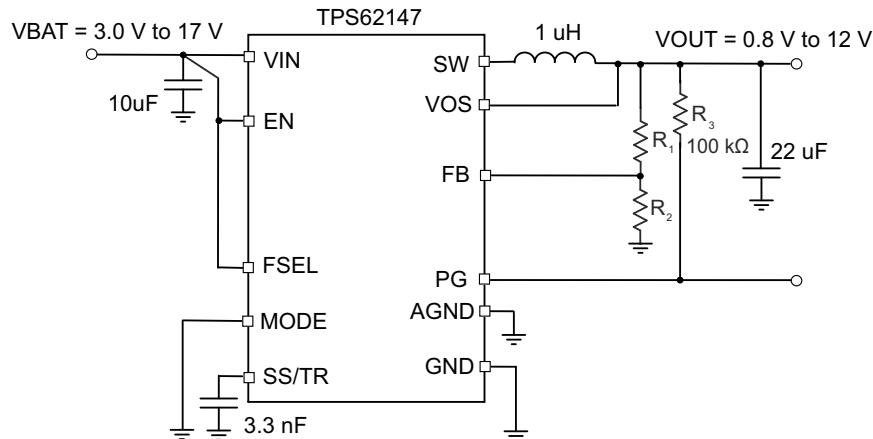
10.2.1.1 Design Requirements

The design guideline provides a component selection to operate the device within the recommended operating conditions. See 表 8-1 for the Bill of Materials used to generate the application curves.

10.2.1.2 Detailed Design Procedure

$$R_1 = R_{2\times}\left(\frac{VOUT}{VFB} - 1\right)$$

(19)

With VFB = 0.7 V:

表 10-4. Setting the Output Voltage

NOMINAL OUTPUT VOLTAGE	R1	R2	EXACT OUTPUT VOLTAGE
0.8 V	51 kΩ	360 kΩ	0.799 V
1.2 V	130 kΩ	180 kΩ	1.206 V
1.5 V	150 kΩ	130 kΩ	1.508 V
1.8 V	470 kΩ	300 kΩ	1.797 V
2.5 V	620 kΩ	240 kΩ	2.508 V
3.3 V	560 kΩ	150 kΩ	3.313 V
5 V	510 kΩ	82 kΩ	5.054 V
9 V	510 kΩ	43 kΩ	9.002 V
12 V	1000 kΩ	62 kΩ	11.99 V
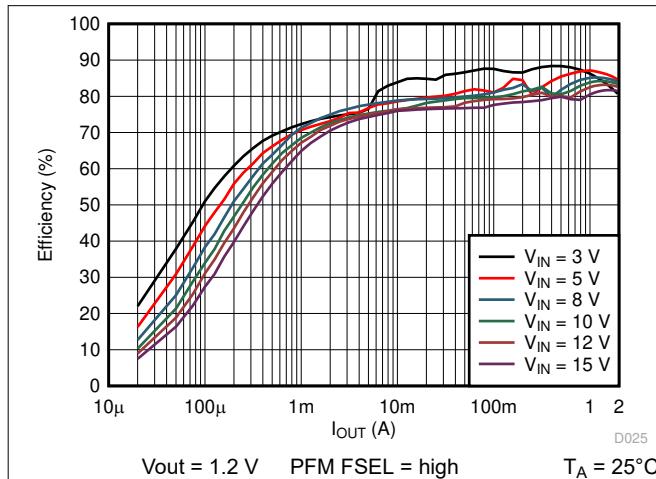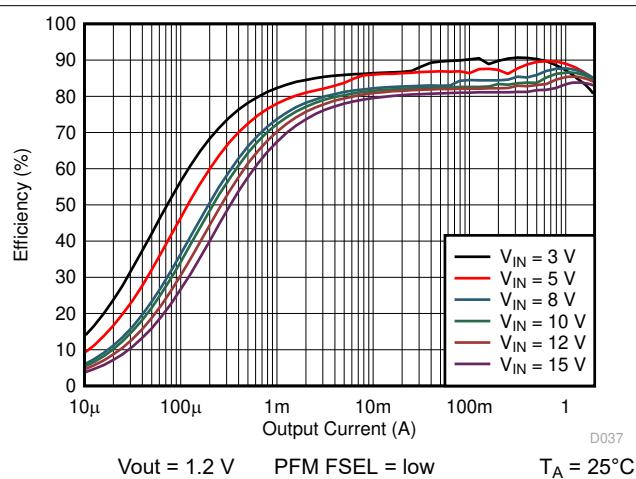
Product Folder Links: TPS62147 TPS62148

English Data Sheet: SLVSDR8

10.2.1.3 Application Curves

Vout = 1.2 V   PFM FSEL = high   T$_A$ = 25°C

图 **10-2. Efficiency vs Output Current**

Vout = 1.2 V   PFM FSEL = low   T$_A$ = 25°C

图 **10-3. Efficiency vs Output Current**

Vout = 1.2 V   PWM FSEL = high   T$_A$ = 25°C

图 **10-4. Efficiency vs Output Current**

Vout = 1.2 V   PWM FSEL = low   T$_A$ = 25°C

图 **10-5. Efficiency vs Output Current**

Vout = 1.8 V   PFM FSEL = high   T$_A$ = 25°C

图 **10-6. Efficiency vs Output Current**

Vout = 1.8 V   PFM FSEL = low   T$_A$ = 25°C

图 **10-7. Efficiency vs Output Current**

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Vout = 1.8 V   PWM FSEL = high   T_A = 25°C

图 10-8. Efficiency vs Output Current

Vout = 1.8 V   PWM FSEL = low   T_A = 25°C

图 10-9. Efficiency vs Output Current

Vout = 3.3 V   PFM FSEL = high   T_A = 25°C

图 10-10. Efficiency vs Output Current

Vout = 3.3 V   PFM FSEL = low   T_A = 25°C

图 10-11. Efficiency vs Output Current

Vout = 3.3 V   PWM FSEL = high   T_A = 25°C

图 10-12. Efficiency vs Output Current

Vout = 3.3 V   PWM FSEL = low   T_A = 25°C

图 10-13. Efficiency vs Output Current

Product Folder Links: *TPS62147 TPS62148*

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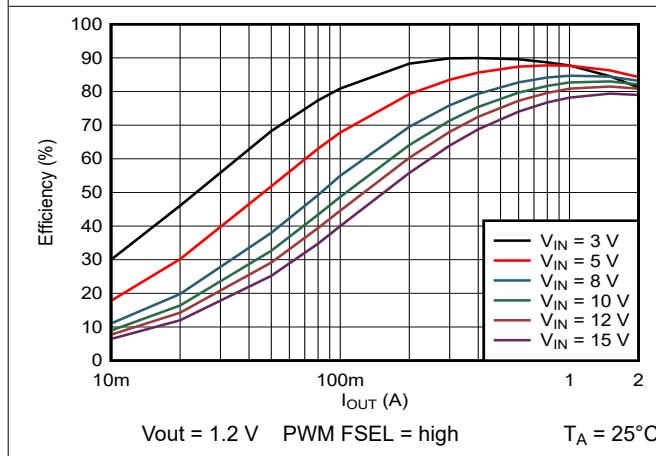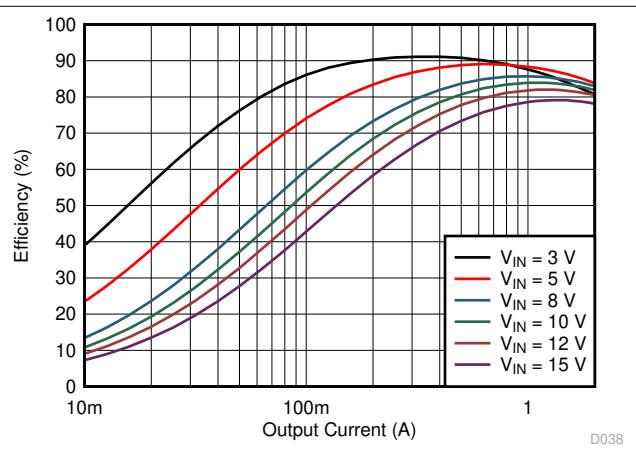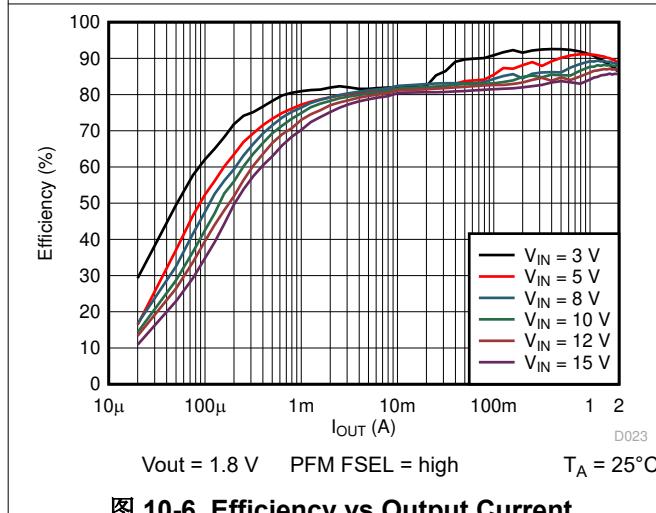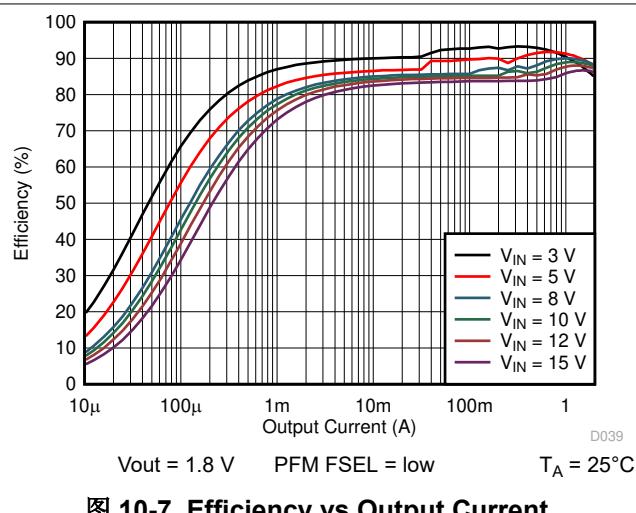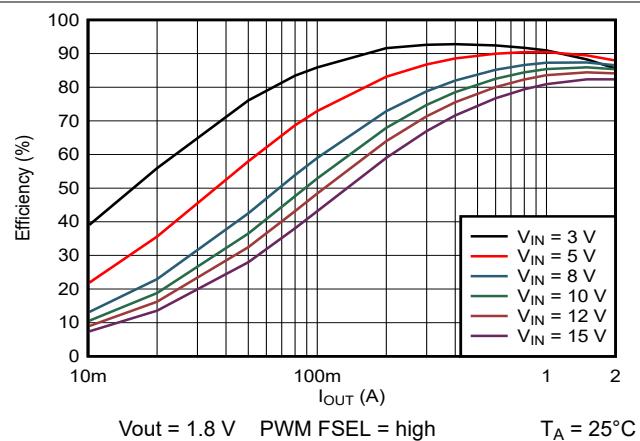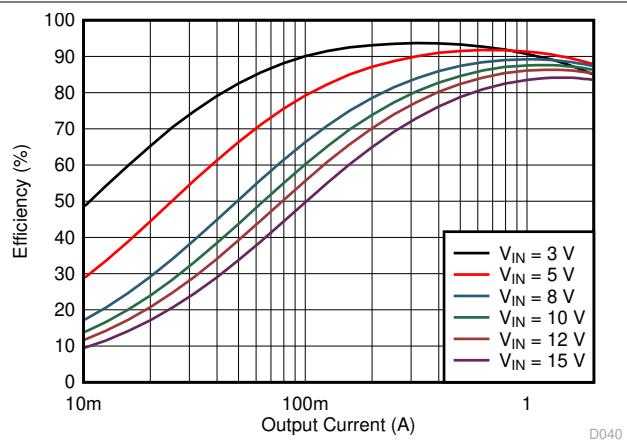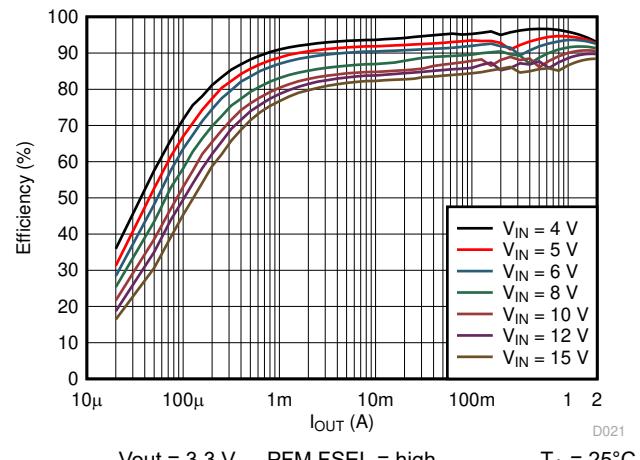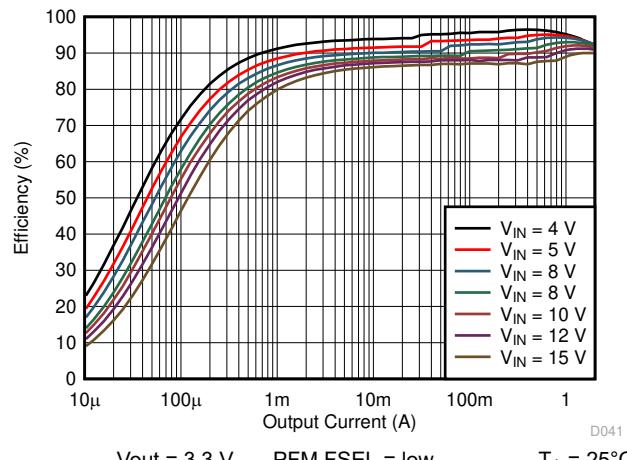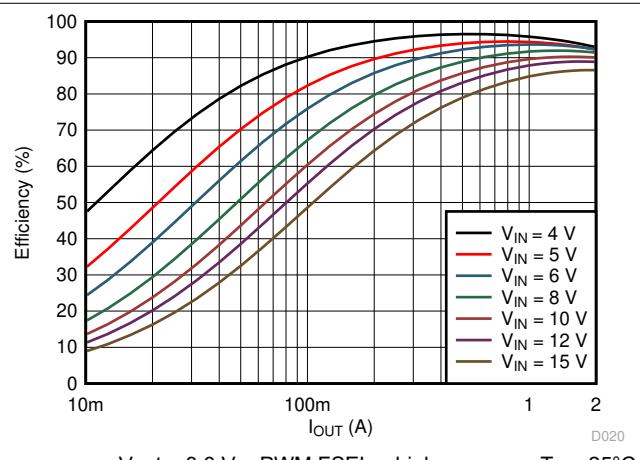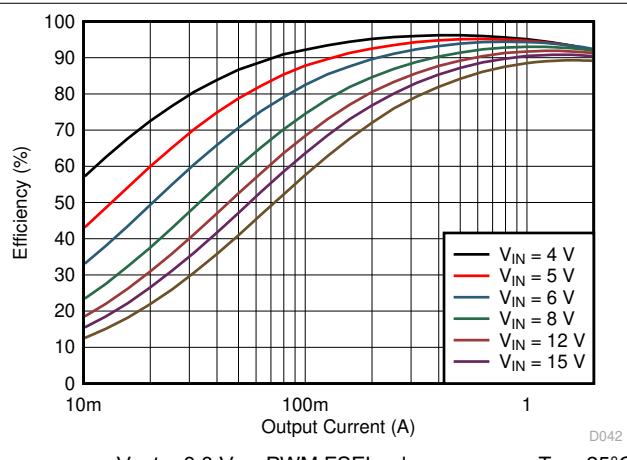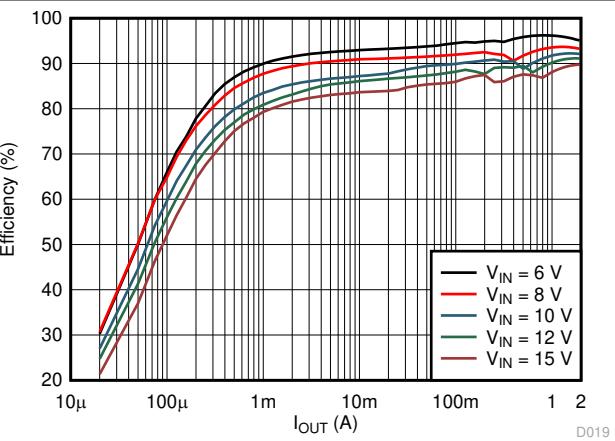
图 **10-14. Efficiency vs Output Current**
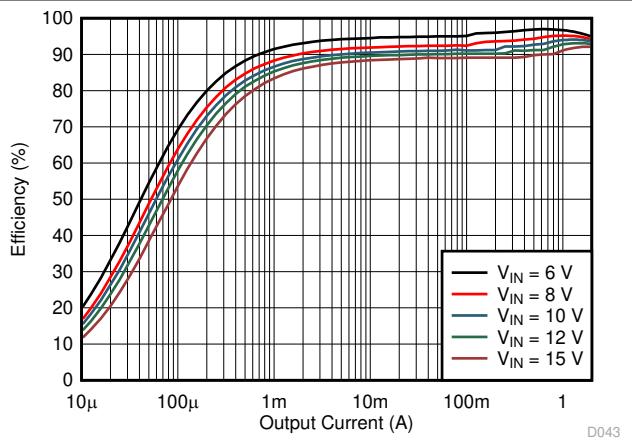
图 **10-15. Efficiency vs Output Current**
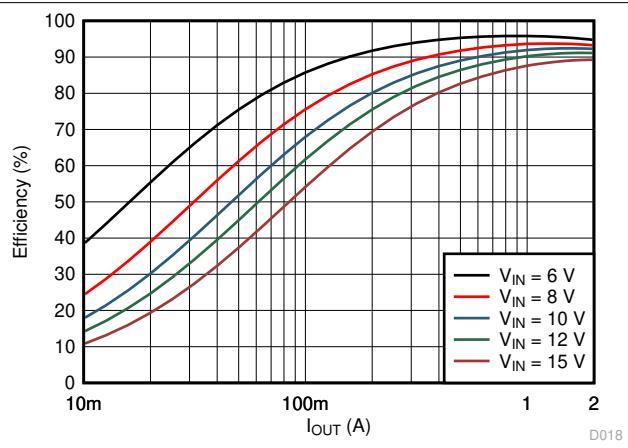
图 **10-16. Efficiency vs Output Current**
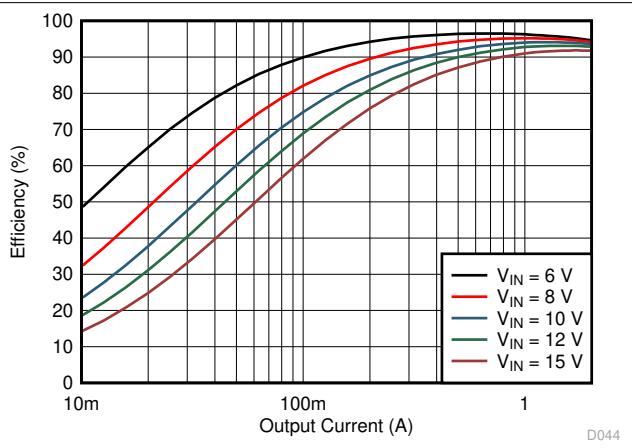
图 **10-17. Efficiency vs Output Current**
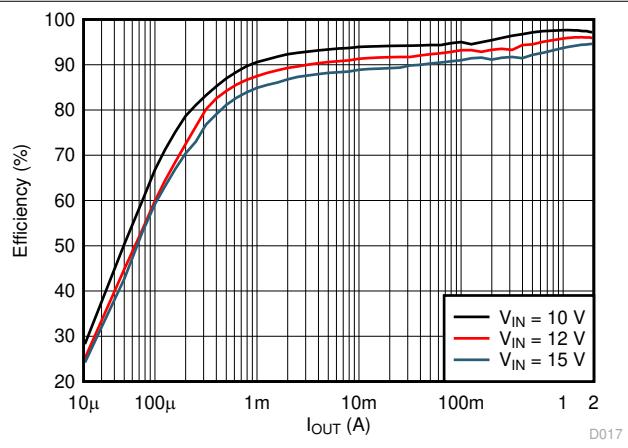
图 **10-18. Efficiency vs Output Current**

图 **10-19. Efficiency vs Output Current**

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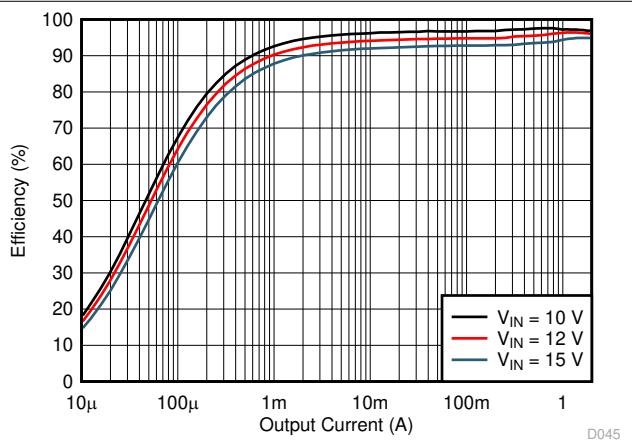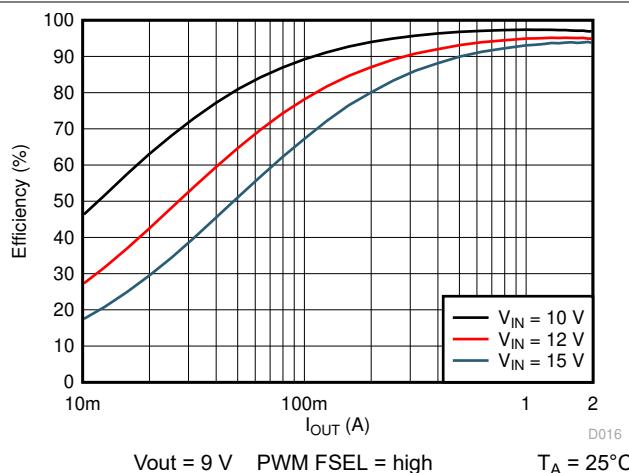
图 10-20. Efficiency vs Output Current
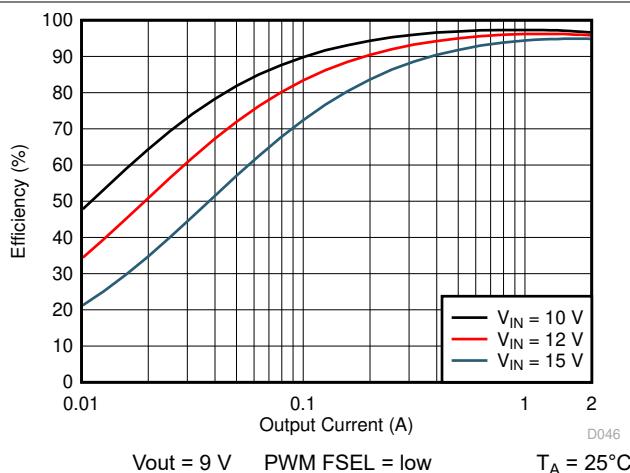
图 10-21. Efficiency vs Output Current
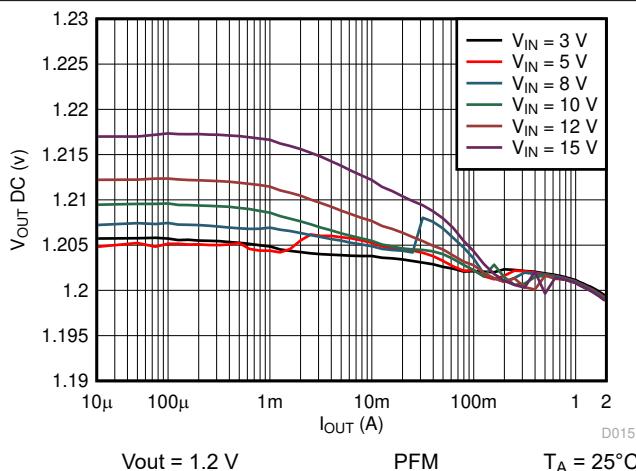
图 10-22. Output Voltage vs Output Current
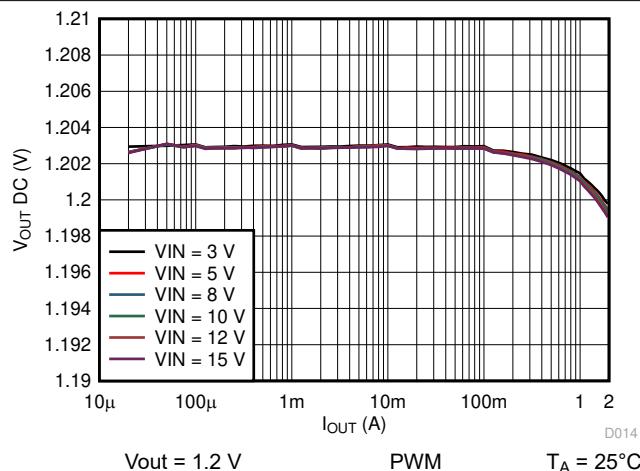
图 10-23. Output Voltage vs Output Current
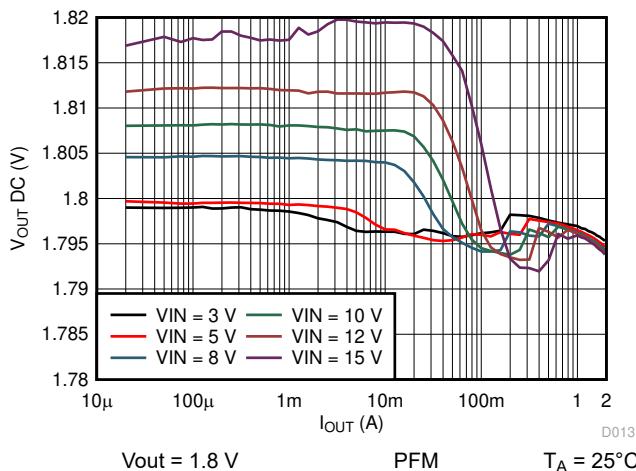
图 10-24. Output Voltage vs Output Current
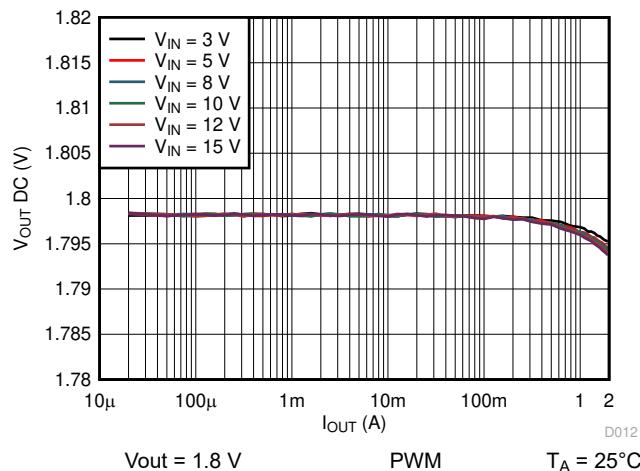
图 10-25. Output Voltage vs Output Current
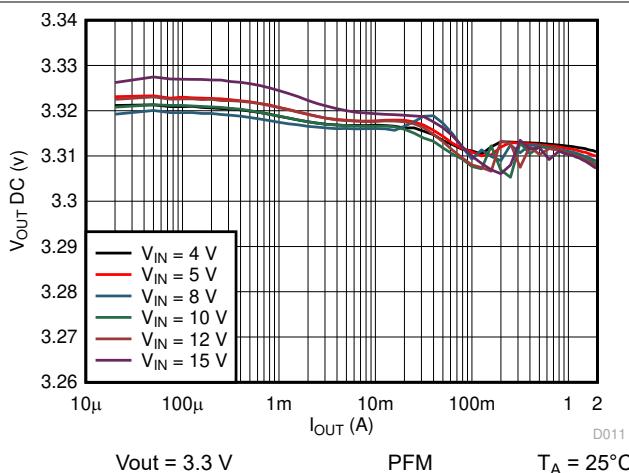
图 10-26. Output Voltage vs Output Current
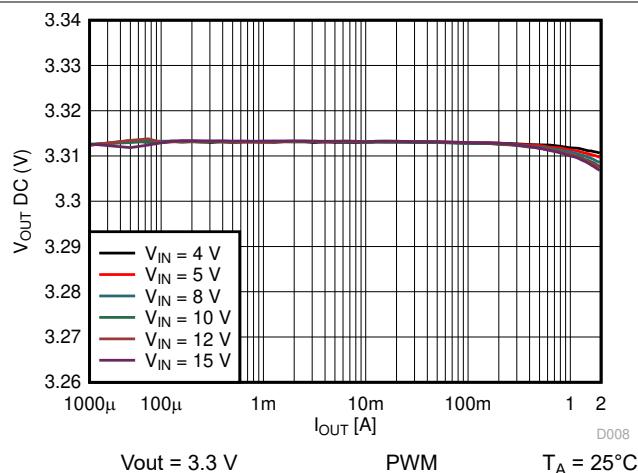
图 10-27. Output Voltage vs Output Current
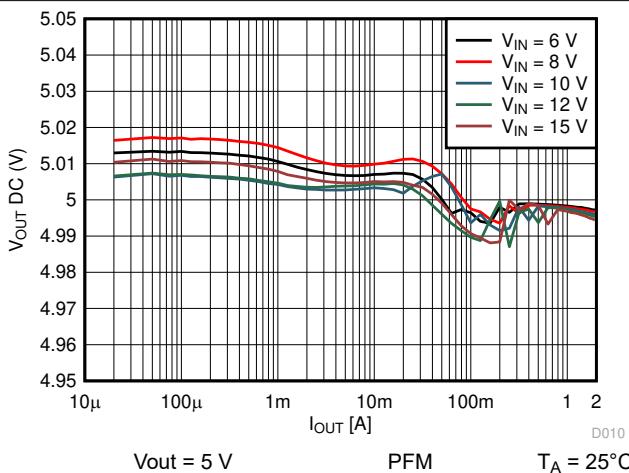
图 10-28. Output Voltage vs Output Current
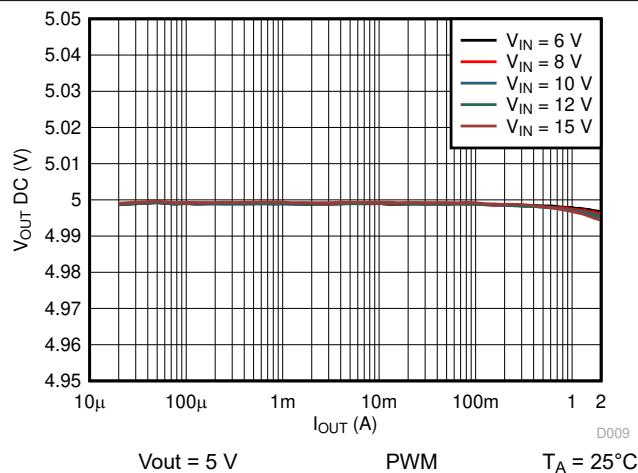
图 10-29. Output Voltage vs Output Current
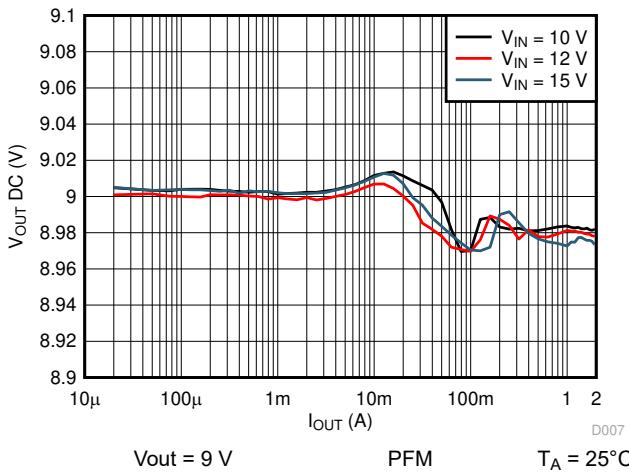
图 10-30. Output Voltage vs Output Current

图 10-31. Load Transient Response

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: SLVSDR8
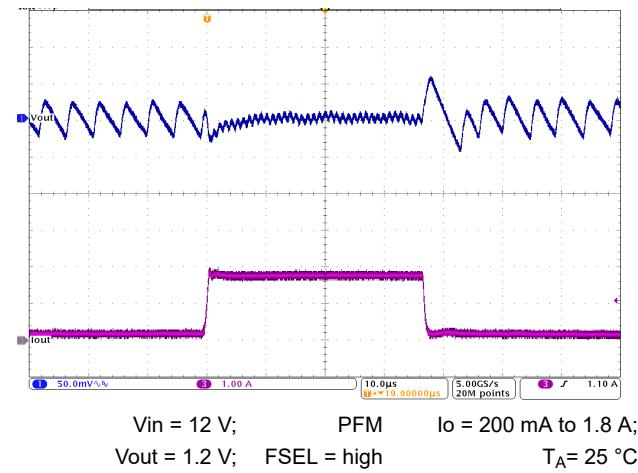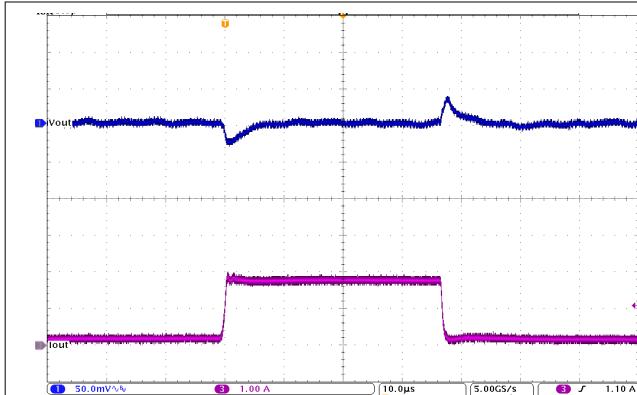
Vin = 12 V;   PWM   Io = 200 mA to 1.8 A
Vout = 1.2 V   FSEL = high T_A= 25 °C

图 10-32. Load Transient Response
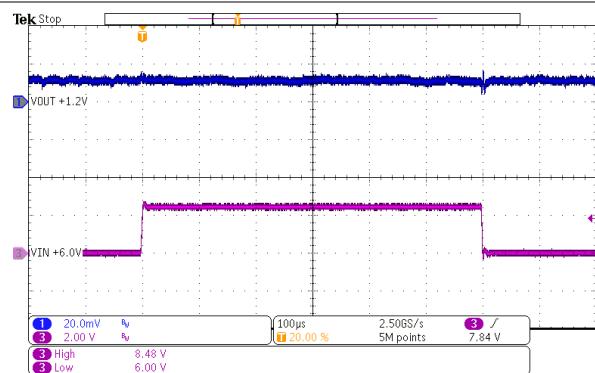
Vin = 6 V to 8.4 V;   PFM   Io = 1 A
Vout = 1.2 V   FSEL = high T_A= 25 °C

图 10-33. Line Transient Response
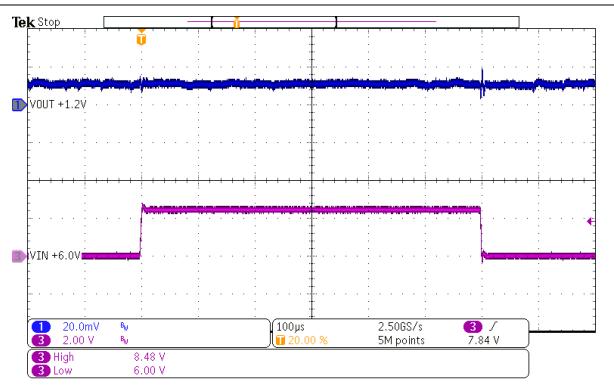
Vin = 6 V to 8.4 V;   PWM   Io = 1 A
Vout = 1.2 V   FSEL = high T_A= 25 °C

图 10-34. Line Transient Response
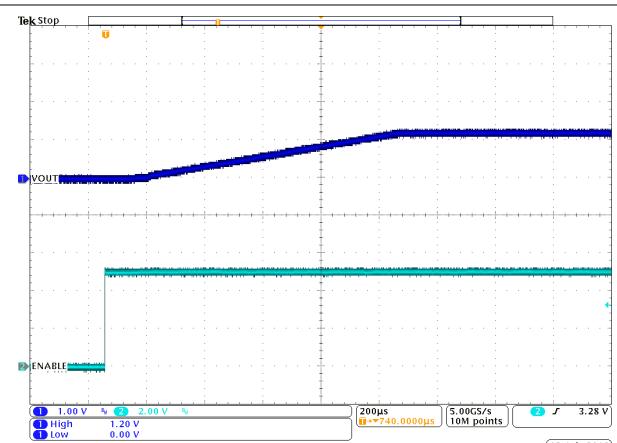
Vin = 5 V;   PFM   Rload = 1 kΩ
Vout = 1.2 V   FSEL = high T_A= 25 °C

图 10-35. Start-Up Timing
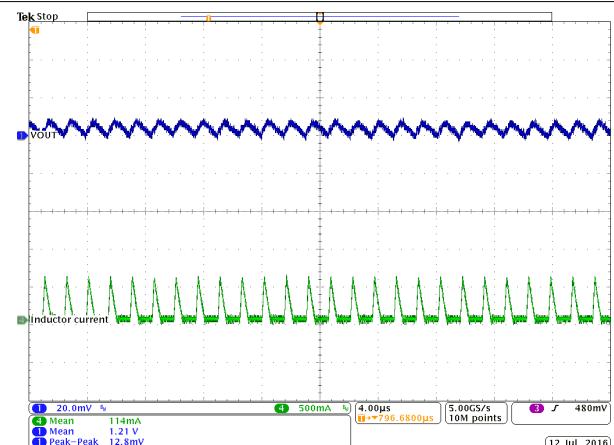
Vin = 5 V;   PFM   Io = 0.1 A
Vout = 1.2 V   FSEL = high T_A= 25 °C

图 10-36. Output Voltage Ripple
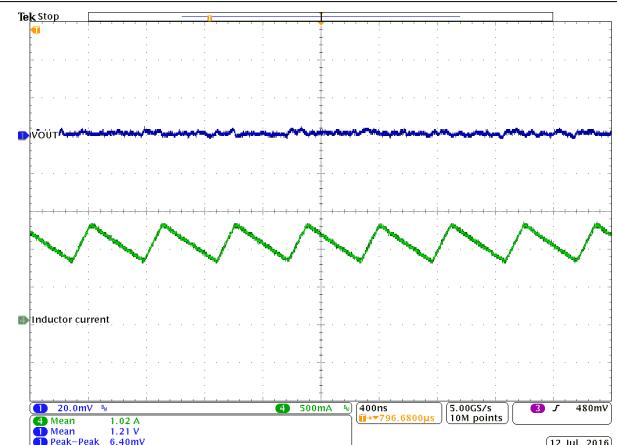
Vin = 5 V;   PWM   Io = 1 A
Vout = 1.2 V   FSEL = high T_A= 25 °C

图 10-37. Output Voltage Ripple

Product Folder Links: TPS62147 TPS62148

English Data Sheet: SLVSDR8
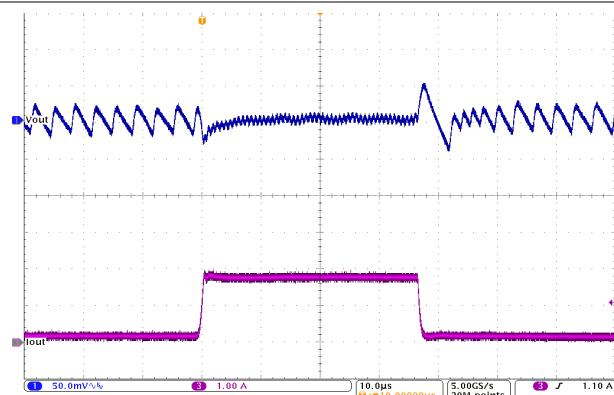
Vin = 12 V   PFM   Io = 200 mA to 1.8 A

Vout = 1.8 V   FSEL = high T_A= 25 °C

图 **10-38. Load Transient Response**
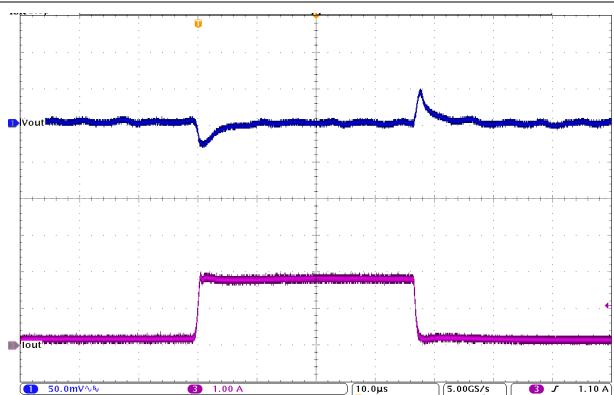
Vin = 12 V   PWM   Io = 200 mA to 1.8 A

Vout = 1.8 V   FSEL = high T_A= 25°C

图 **10-39. Load Transient Response**
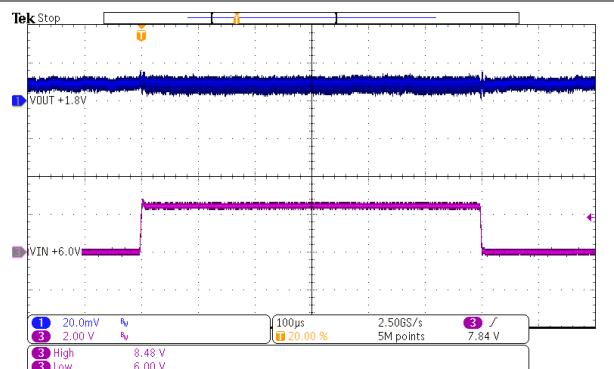
Vin = 6 V to 8.4 V;   PFM   Io = 1 A

Vout = 1.8 V   FSEL = high T_A= 25 °C

图 **10-40. Line Transient Response**
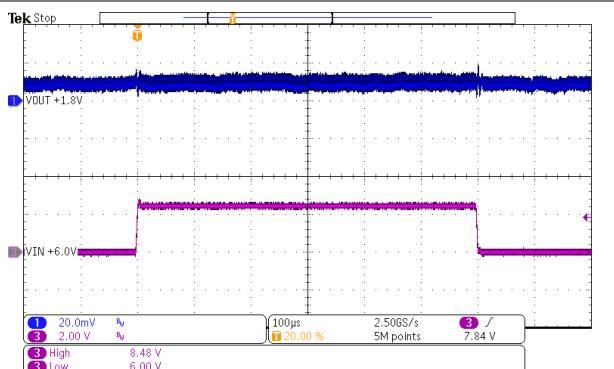
Vin = 6 V to 8.4 V;   PWM   Io = 1 A

Vout = 1.8 V   FSEL = high T_A= 25 °C

图 **10-41. Line Transient Response**
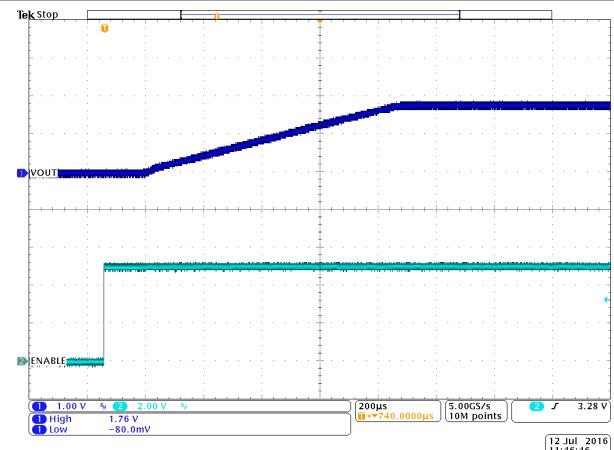
Vin = 5 V   PWM   Rload = 1 kΩ

Vout = 1.8 V   FSEL = high T_A= 25 °C

图 **10-42. Start-Up Timing**
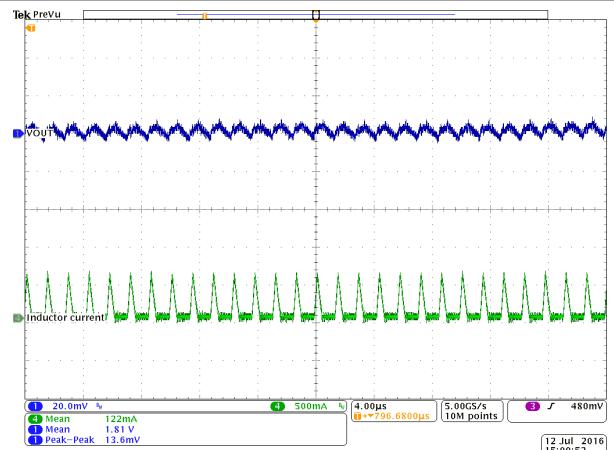
Vin = 5 V   PFM   Io = 0.1 A

Vout = 1.8 V   FSEL = high T_A= 25 °C

图 **10-43. Output Voltage Ripple**

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*
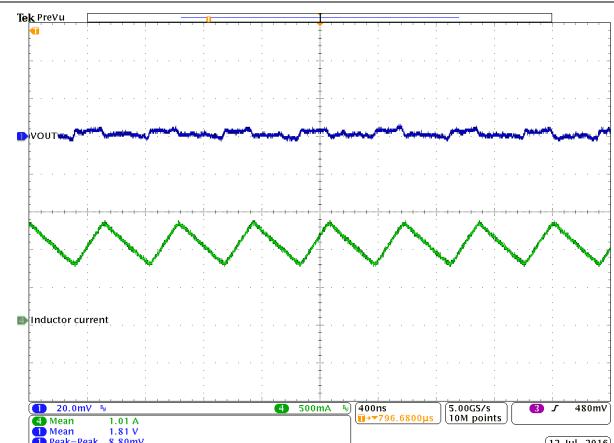
Vin = 5 V PWM Io = 1 A

Vout = 1.8 V FSEL = high T_A= 25 °C

图 **10-44. Output Voltage Ripple**
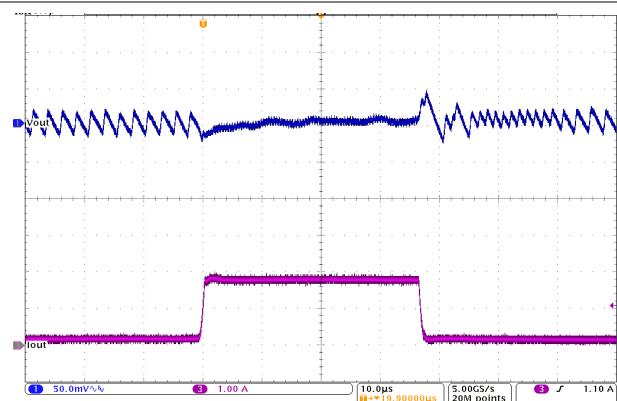
Vin = 12 V PFM Io = 200 mA to 1.8 A

Vout = 3.3 V FSEL = high T_A = 25 °C

图 **10-45. Load Transient Response**
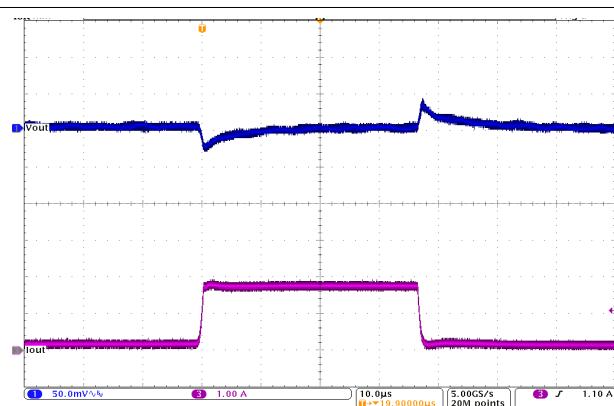
Vin = 12 V PWM Io = 200 mA to 1.8 A

Vout = 3.3 V FSEL = high T_A = 25 °C

图 **10-46. Load Transient Response**
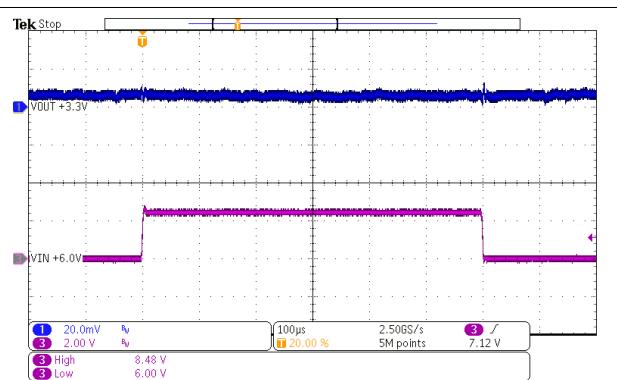
Vin = 6 V to 8.4 V; PFM Io = 1 A

Vout = 3.3 V FSEL = high T_A= 25 °C

图 **10-47. Line Transient Response**
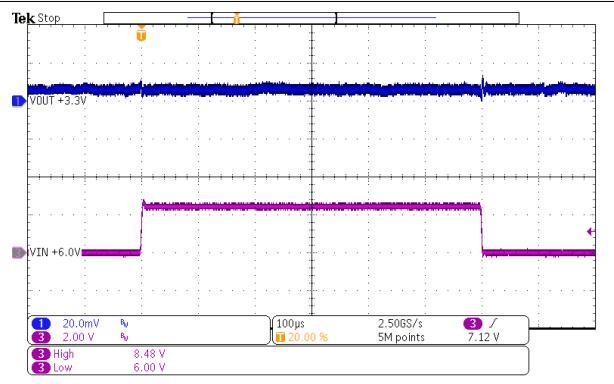
Vin = 6 V to 8.4 V; PWM Io = 1 A

Vout = 3.3 V FSEL = high T_A= 25 °C

图 **10-48. Line Transient Response**
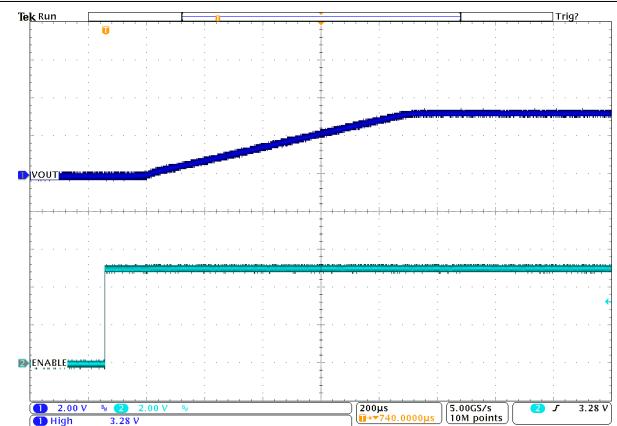
Vin = 5V PWM Rload = 1 k Ω

Vout = 3.3 V FSEL = high T_A= 25 °C

图 **10-49. Start-Up Timing**

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

Vin = 12 V   PFM   Io = 0.1 A
Vout = 3.3 V   FSEL = high   T$_A$= 25 °C

图 **10-50. Output Voltage Ripple**

Vin = 12 V   PWM   Io = 1 A
Vout = 3.3 V   FSEL = high   T$_A$= 25 °C

图 **10-51. Output Voltage Ripple**

Vin = 12 V   PFM   Io = 200 mA to 1.8 A
Vout = 5 V   FSEL = high   T$_A$= 25 °C

图 **10-52. Load Transient Response**

Vin = 12 V   PWM   Io = 200 mA to 1.8 A
Vout = 5 V   FSEL = high   T$_A$= 25 °C

图 **10-53. Load Transient Response**

Vin = 6 V to 8.4 V;   PFM   Io = 1 A
Vout = 5 V   FSEL = high   T$_A$= 25 °C

图 **10-54. Line Transient Response**

Vin = 6 V to 8.4 V;   PWM   Io = 1 A
Vout = 5 V   FSEL = high   T$_A$= 25 °C

图 **10-55. Line Transient Response**

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*
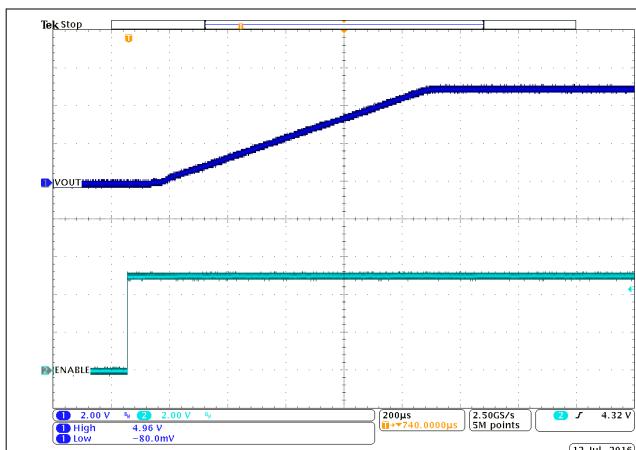
Vin = 12 V   PWM   Rload = 1 kΩ

Vout = 5 V   FSEL = high T_A= 25 °C

图 **10-56. Start-Up Timing**
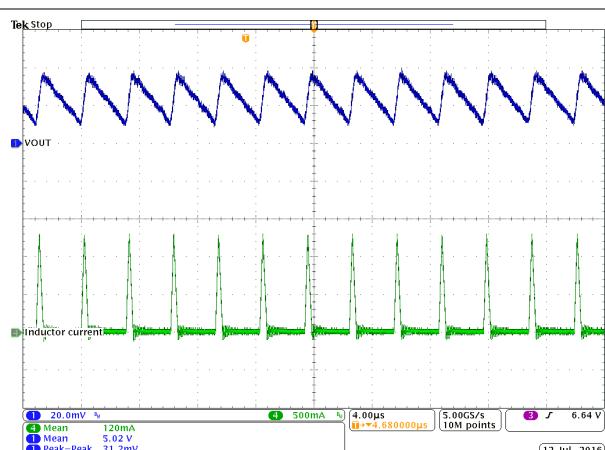
Vin = 12 V   PFM   Io = 0.1 A

Vout = 5 V   FSEL = high T_A= 25 °C

图 **10-57. Output Voltage Ripple**
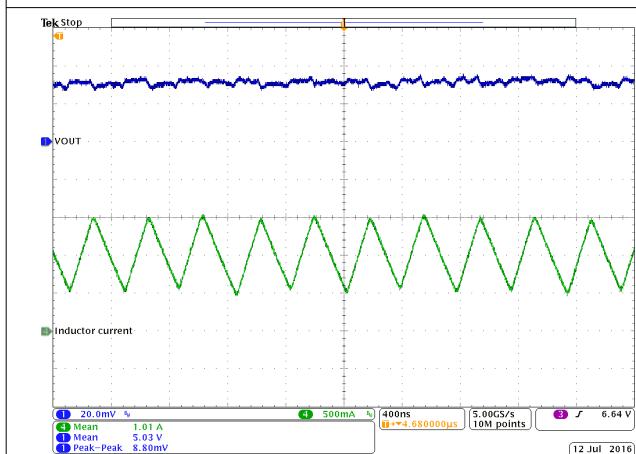
Vin = 12 V   PWM   Io = 1 A

Vout = 5 V   FSEL = high T_A= 25 °C

图 **10-58. Output Voltage Ripple**
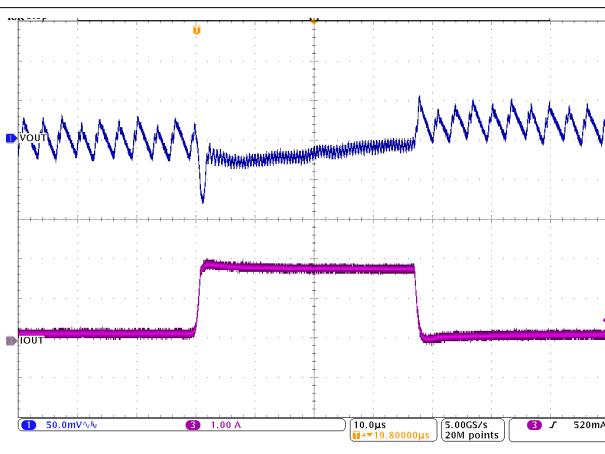
Vin = 12 V   PFM   Io = 200 mA to 1.8 A

Vout = 9 V   FSEL = high T_A= 25 °C

图 **10-59. Load Transient Response**
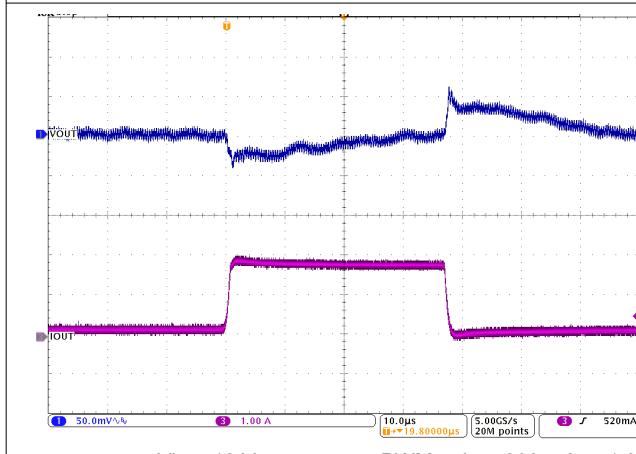
Vin = 12 V   PWM   Io = 200 mA to 1.8 A

Vout = 9 V   FSEL = high T_A= 25 °C

图 **10-60. Load Transient Response**
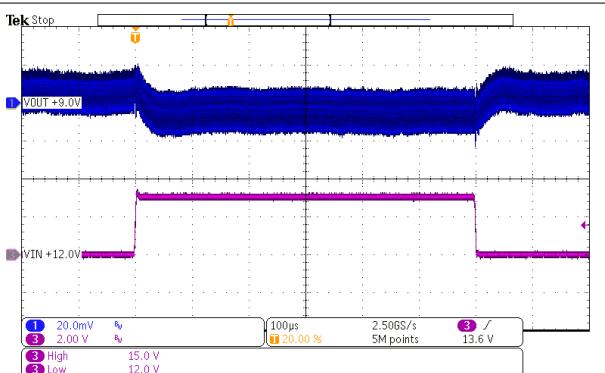
Vin = 12 V to 15 V;   PFM   Io = 1 A

Vout = 9 V   FSEL = high T_A= 25 °C

图 **10-61. Line Transient Response**
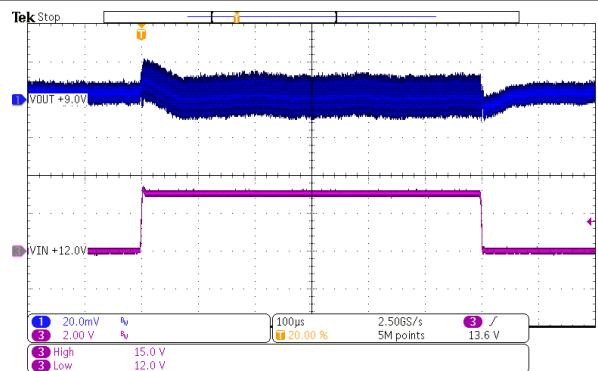
Submit Document Feedback   29

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

Vin = 12 V to 15 V;   PWM   Io = 1 A
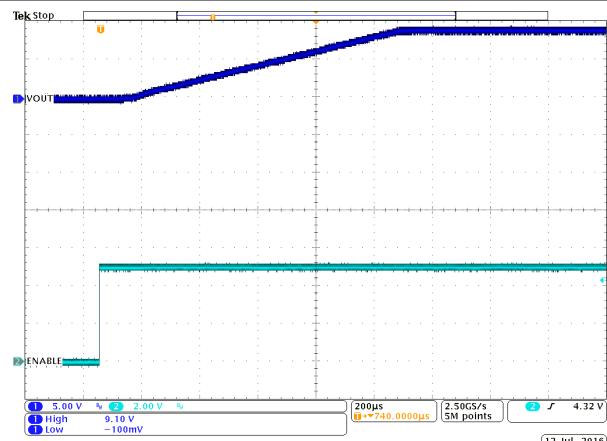
Vout = 9 V   FSEL = high   T$_A$= 25 °C

图 **10-62. Line Transient Response**

Vin = 12 V   PWM   Rload = 1 kΩ

Vout = 9 V   FSEL = high   T$_A$= 25 °C

图 **10-63. Start-Up Timing**

Vin = 12 V   PFM   Io = 0.1 A
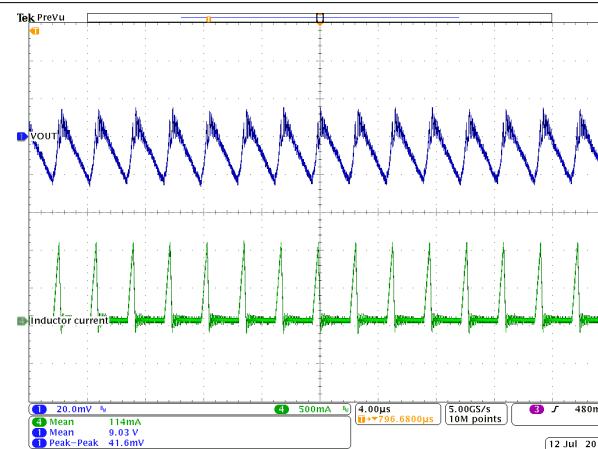
Vout = 9 V   FSEL = high   T$_A$= 25 °C

图 **10-64. Output Voltage Ripple**

Vin = 12 V   PWM   Io = 1 A
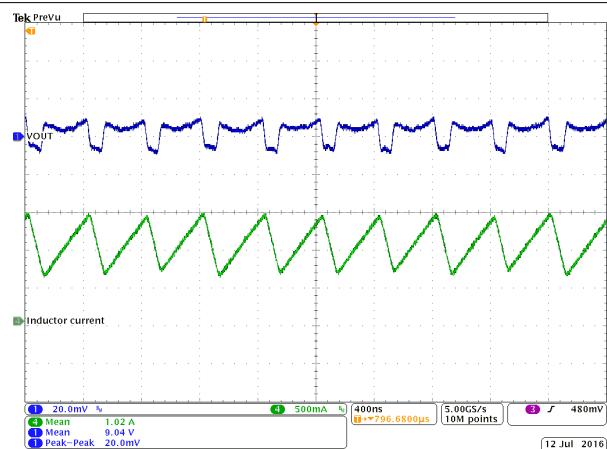
Vout = 9 V   FSEL = high   T$_A$= 25 °C

图 **10-65. Output Voltage Ripple**
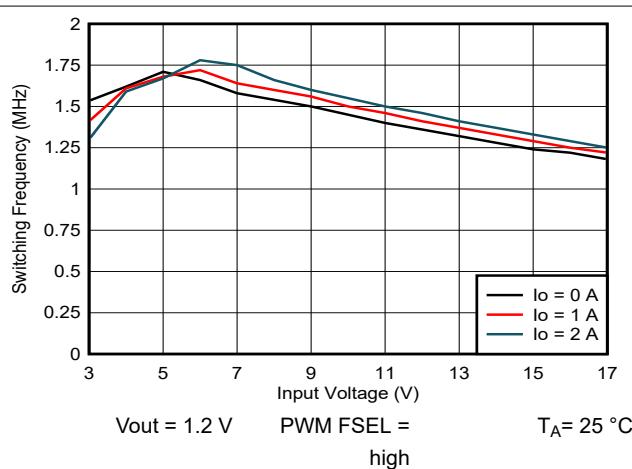
Vout = 1.2 V   PWM FSEL =   T$_A$= 25 °C

high

图 **10-66. Switching Frequency vs Input Voltage**
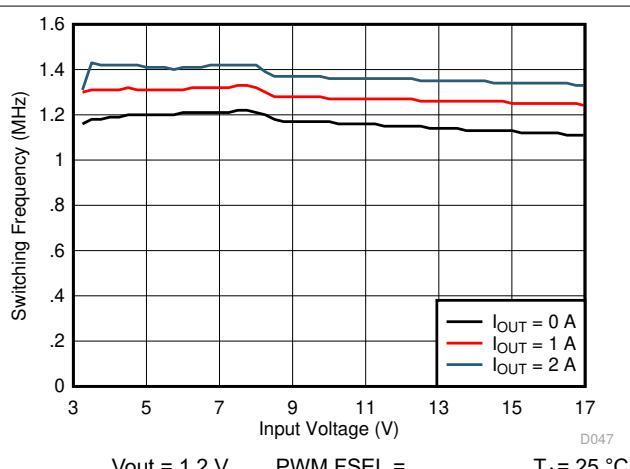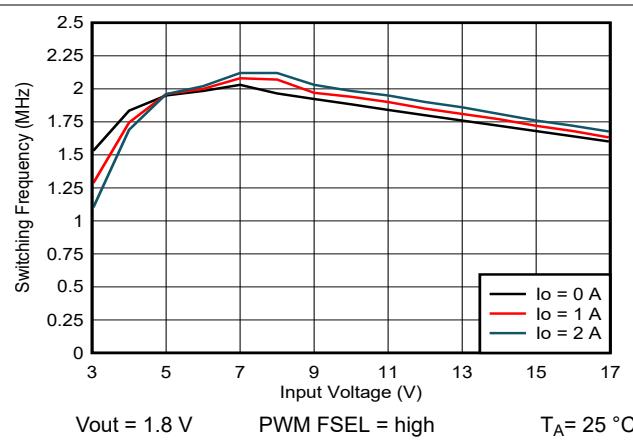
Vout = 1.2 V   PWM FSEL =   T$_A$= 25 °C

low

图 **10-67. Switching Frequency vs Input Voltage**

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: *SLVSDR8*

图 10-68. Switching Frequency vs Input Voltage

Vout = 1.8 V   PWM FSEL = high T_A = 25 °C

图 10-69. Switching Frequency vs Input Voltage

Vout = 1.8 V   PWM FSEL = low T_A = 25 °C

图 10-70. Switching Frequency vs Input Voltage

Vout = 3.3 V   PWM FSEL = high T_A = 25 °C

图 10-71. Switching Frequency vs Input Voltage

Vout = 3.3 V   PWM FSEL = low T_A = 25 °C

图 10-72. Switching Frequency vs Junction Temperature

Vout = 3.3 V   PWM FSEL = high   Iout = 1 A

图 10-73. Switching Frequency vs Input Voltage

Vout = 5 V   PWM FSEL = high T_A = 25 °C

Product Folder Links: TPS62147 TPS62148

English Data Sheet: SLVSDR8

Vout = 5 V   PWM FSEL = low T_A= 25 °C

图 **10-74. Switching Frequency vs Input Voltage**

Vout = 5 V   PWM FSEL = high   Iout = 1 A

图 **10-75. Switching Frequency vs Junction Temperature**

Vout = 9 V   PWM FSEL = high T_A= 25 °C

图 **10-76. Switching Frequency vs Input Voltage**

Vout = 9 V   PWM FSEL = low T_A= 25 °C

图 **10-77. Switching Frequency vs Input Voltage**


Vout = 9.0 V   PWM FSEL = high   Iout = 1 A
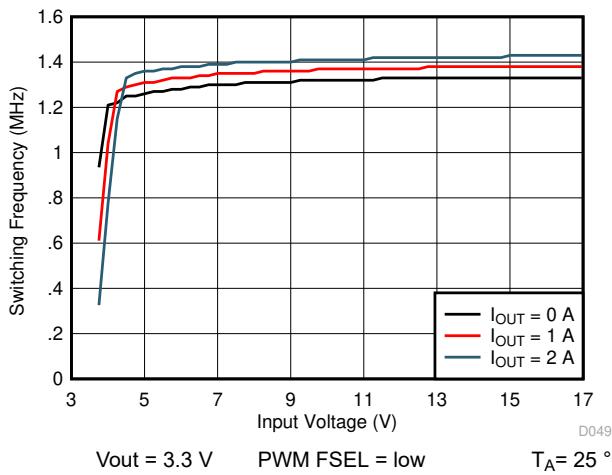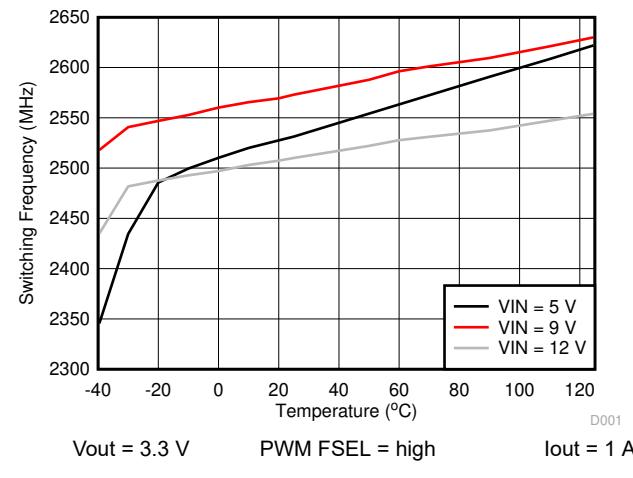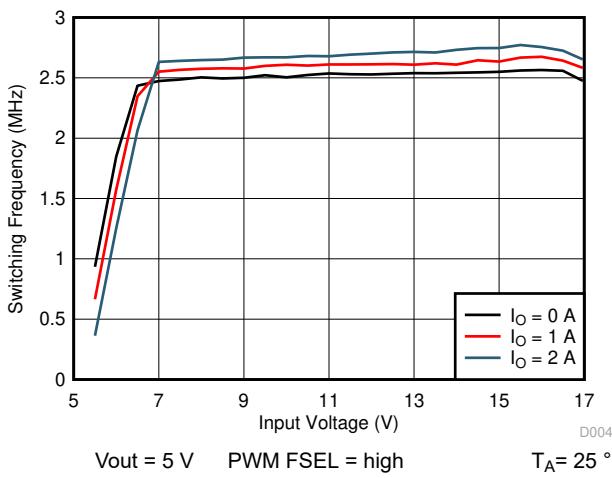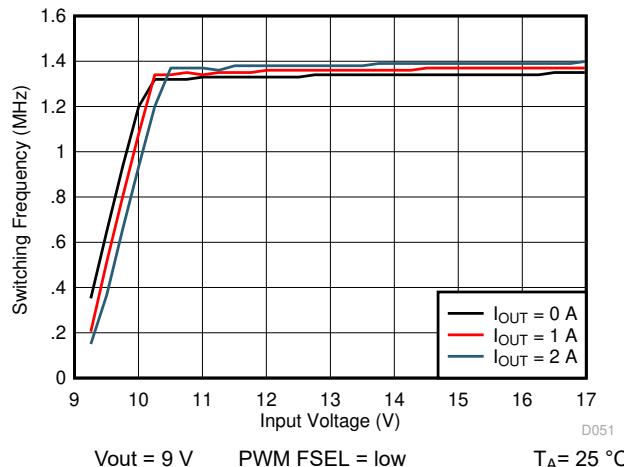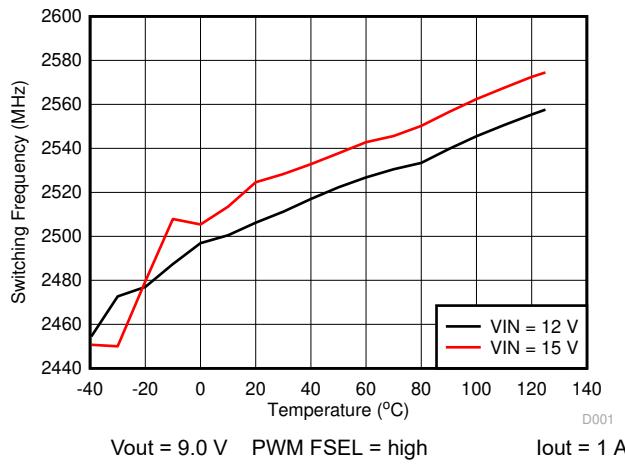
图 **10-78. Switching Frequency vs Junction Temperature**
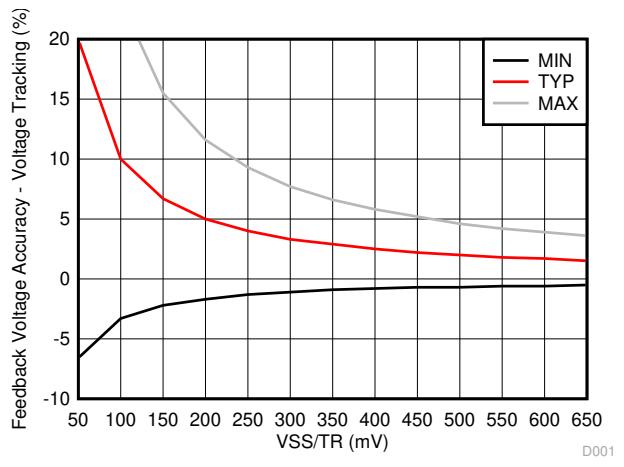
图 **10-79. Feedback Voltage Accuracy with Voltage Tracking vs Voltage at VSS/TR**

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: SLVSDR8

10.3 System Examples

10.3.1 LED Power Supply

The TPS62147, TPS62148 can be used as a power supply for power LEDs. The FB pin can be easily set down to lower values than nominal by using the SS/TR pin. With that, the voltage drop on the sense resistor is low to avoid excessive power loss. Because this pin provides 2.5 µA, the feedback pin voltage can be adjusted by an external resistor per 方程式 20. This drop, proportional to the LED current, is used to regulate the output voltage (anode voltage) to a proper level to drive the LED. Both analog and PWM dimming are supported with the TPS62147, TPS62148.

图 10-80 shows an application circuit, tested with analog dimming:
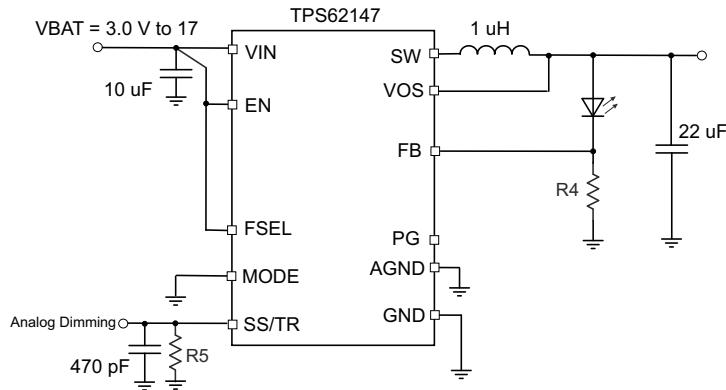

图 10-80. Single Power LED Supply

The resistor at SS/TR defines the FB voltage. It is set to 350 mV by R5 = 140 kΩ using 方程式 20. This cuts the losses on R4 to half from the nominal 0.7 V of feedback voltage while it still provides good accuracy.

$$V_{FB} = 2.5\mu A \times R_{SS/TR} + 11mV$$

(20)

The device supplies a constant current set by resistor R4 from FB to GND. The minimum input voltage has to be rated according the forward voltage needed by the LED used. More information is available in the Application Note SLVA451.

10.3.2 Powering Multiple Loads

In applications where TPS62147, TPS62148 are used to power multiple load circuits, it can be the case that the total capacitance on the output is very large. To properly regulate the output voltage, there must be an appropriate AC signal level on the VOS pin. Tantalum capacitors have a large enough ESR to keep output voltage ripple sufficiently high on the VOS pin. With low ESR ceramic capacitors, the output voltage ripple can get very low, so it is not recommended to use a large capacitance directly on the output of the device. If there are several load circuits with their associated input capacitor on a pcb, these loads are typically distributed across the board. This adds enough trace resistance (R_{trace}) to keep a large enough AC signal on the VOS pin for proper regulation.

The minimum total trace resistance on the distributed load is 10 mΩ. The total capacitance n × Cin in the use case below was 32 × 47 uF of ceramic X7R capacitors.
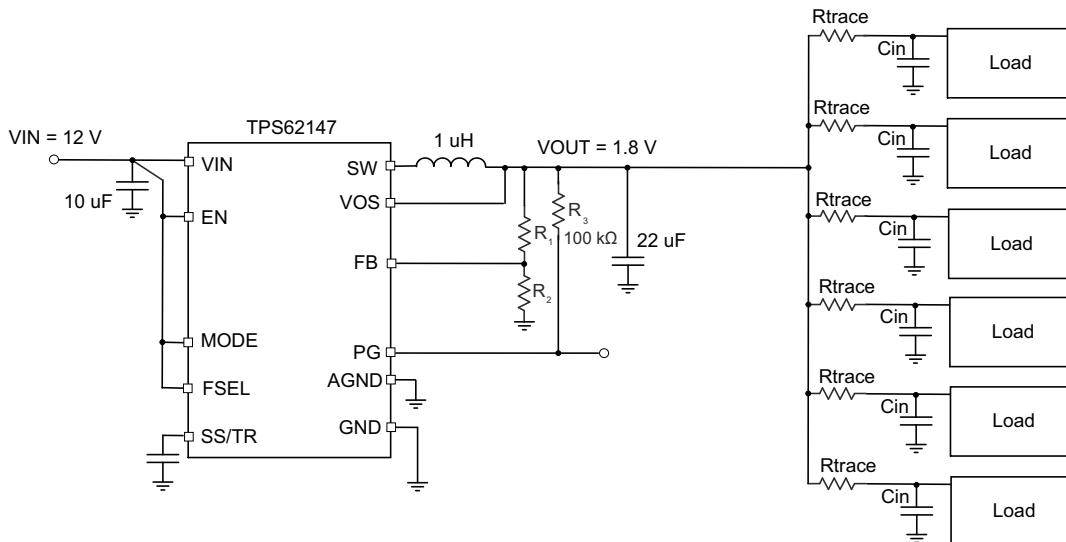
图 **10-81. Multiple Loads**

### 10.3.3 Voltage Tracking

DEVICE 2 follows the voltage applied to the SS/TR pin. A ramp on SS/TR to 0.7 V ramps the output voltage according to the 0.7 V reference.

Tracking the 3.3 V of DEVICE 1 requires a resistor divider on SS/TR of DEVICE 2 equal to the output voltage divider of DEVICE 1.


图 **10-82. Tracking Example**

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: SLVSDR8
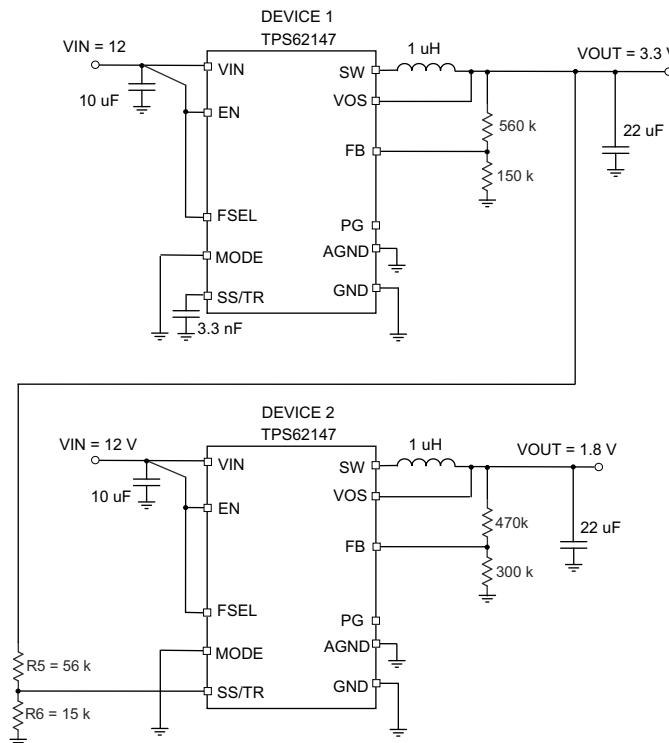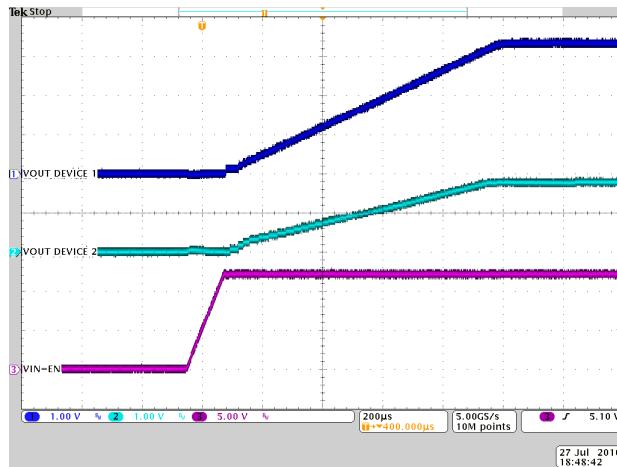
图 **10-83. Tracking**

10.3.4 Precise Soft-Start Timing

The SS/TR pin of the TPS62147, TPS62148 can be used for tracking as well as for setting the soft-start time. The TPS62147, TPS62148 has one GND terminal which is used for the power ground as well as for the analog ground connection. While starting the device with a load current above approximately 1 A, the noise on the GND connection can lead to a soft-start time shorter than calculated. There is an external work around as given below.

Adding a 10 kΩ resistor filters the noise on the GND connection and keeps the soft-start time at the value calculated.
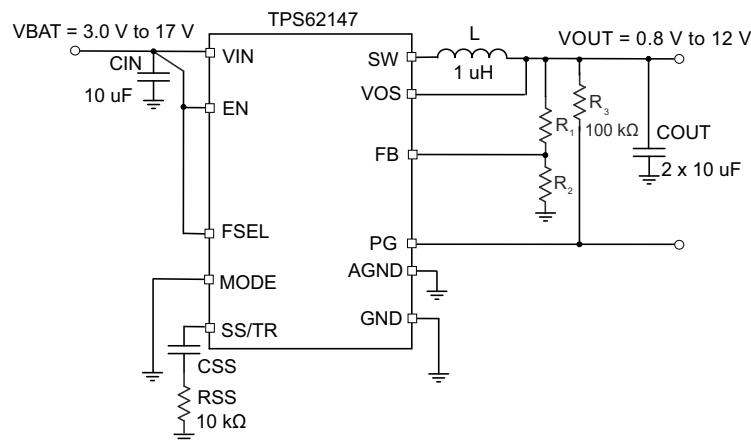
图 **10-84. Adding a Series Resistor to CSS**

10.4 Power Supply Recommendations

The power supply to the TPS62147, TPS62148 must have a current rating according to the supply voltage, output voltage, and output current of the TPS62147, TPS62148.

10.5 Layout

10.5.1 Layout Guidelines

A proper layout is critical for the operation of a switched mode power supply, even more at high switching frequencies. Therefore the PCB layout of the TPS62147, TPS62148 demands careful attention to ensure operation and to get the performance specified. A poor layout can lead to issues like poor regulation (both line and load), stability and accuracy weaknesses, increased EMI radiation and noise sensitivity.

See 节 10.5.2 for the recommended layout of the TPS62147, TPS62148, which is designed for common external ground connections. The input capacitor must be placed as close as possible between the VIN and GND pin of TPS62147, TPS62148. Also connect the VOS pin in the shortest way to VOUT at the output capacitor.

Provide low inductive and resistive paths for loops with high di/dt. Therefore paths conducting the switched load current must be as short and wide as possible. Provide low capacitive paths (with respect to all other nodes) for wires with high dv/dt. Therefore the input and output capacitance must be placed as close as possible to the IC pins and parallel wiring over long distances as well as narrow traces must be avoided. Loops which conduct an alternating current must outline an area as small as possible, as this area is proportional to the energy radiated.

Sensitive nodes like FB and VOS must be connected with short wires and not nearby high dv/dt signals (for example SW). As they carry information about the output voltage, they must be connected as close as possible to the actual output voltage (at the output capacitor). The capacitor on the SS/TR pin as well as the FB resistors, R1 and R2, must be kept close to the IC and connect directly to those pins and the system ground plane. The same applies to R3 if FB2 is used to scale the output voltage.

The package uses the pins for power dissipation. Thermal vias on the VIN, GND and SW pins help to spread the heat through the pcb.

In case any of the digital inputs EN, FSEL or MODE must be tied to the input supply voltage at VIN, the connection must be made directly at the input capacitor as indicated in the schematics. Please also see the EVM User´s Guide SLVUBE9.

10.5.2 Layout Example
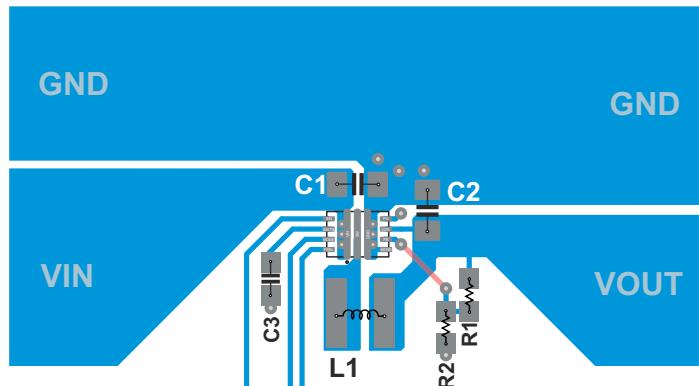
图 **10-85. Layout**

10.5.3 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance are listed below:

- Improving the power dissipation capability of the PCB design, for example, increasing copper thickness, thermal vias, number of layers
- Introducing airflow in the system

For more details on how to use the thermal parameters, see the application notes: Thermal Characteristics Application Note (*Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs*), and (*Semiconductor and IC Package Thermal Metrics application report*).

The TPS62147, TPS62148 are designed for a maximum operating junction temperature (T_J) of 125 °C. Therefore the maximum output power is limited by the power losses that can be dissipated over the actual thermal resistance, given by the package and the surrounding PCB structures. If the thermal resistance of the

package is given, the size of the surrounding copper area and a proper thermal connection of the IC can reduce the thermal resistance. To get an improved thermal behavior, TI recommends to use top layer metal to connect the device with wide and thick metal lines. Internal ground layers can connect to vias directly under the IC for improved thermal performance.

If short circuit or overload conditions are present, the device is protected by limiting internal power dissipation.

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11 Device and Documentation Support

11.1 Device Support

11.1.1 第三方产品免责声明

TI 发布的与第三方产品或服务有关的信息，不能构成与此类产品或服务或保修的适用性有关的认可，不能构成此类产品或服务单独或与任何 TI 产品或服务一起的表示或认可。

11.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新*进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

11.3 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
所有商标均为其各自所有者的财产。

11.5 静电放电警告

静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

11.6 术语表

TI 术语表　　　　　本术语表列出并解释了术语、首字母缩略词和定义。

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: *TPS62147 TPS62148*

English Data Sheet: SLVSDR8

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS62147RGXR	Active	Production	VQFN-HR (RGX) | 11	3000 | LARGE T&R	Yes	Call TI | Sn	Level-1-260C-UNLIM	-40 to 125	62147
TPS62147RGXR.A	Active	Production	VQFN-HR (RGX) | 11	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62147
TPS62147RGXR.B	Active	Production	VQFN-HR (RGX) | 11	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62147
TPS62147RGXT	Active	Production	VQFN-HR (RGX) | 11	250 | SMALL T&R	Yes	Call TI | Sn	Level-1-260C-UNLIM	-40 to 125	62147
TPS62147RGXT.A	Active	Production	VQFN-HR (RGX) | 11	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62147
TPS62147RGXT.B	Active	Production	VQFN-HR (RGX) | 11	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62147
TPS62148RGXR	Active	Production	VQFN-HR (RGX) | 11	3000 | LARGE T&R	Yes	Call TI | Sn	Level-1-260C-UNLIM	-40 to 125	62148
TPS62148RGXR.A	Active	Production	VQFN-HR (RGX) | 11	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62148
TPS62148RGXR.B	Active	Production	VQFN-HR (RGX) | 11	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62148
TPS62148RGXT	Active	Production	VQFN-HR (RGX) | 11	250 | SMALL T&R	Yes	Call TI | Sn	Level-1-260C-UNLIM	-40 to 125	62148
TPS62148RGXT.A	Active	Production	VQFN-HR (RGX) | 11	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62148
TPS62148RGXT.B	Active	Production	VQFN-HR (RGX) | 11	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	62148

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS
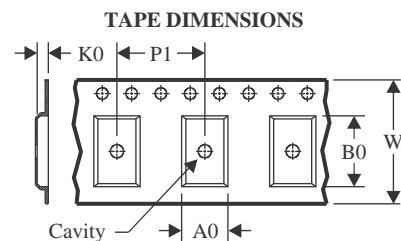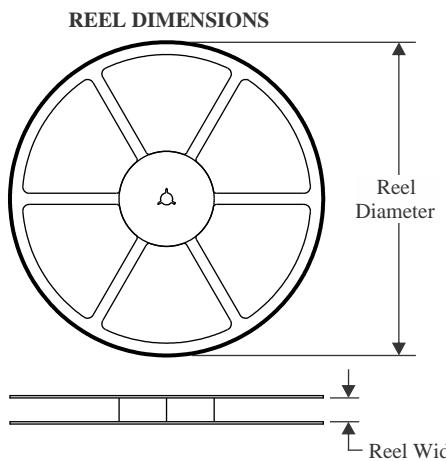
TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
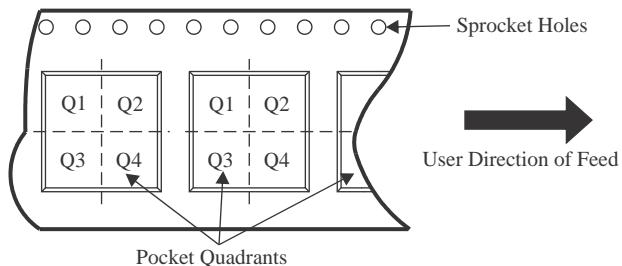

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62147RGXR	VQFN-HR	RGX	11	3000	180.0	8.4	2.25	3.25	1.05	4.0	8.0	Q1
TPS62147RGXT	VQFN-HR	RGX	11	250	180.0	8.4	2.25	3.25	1.05	4.0	8.0	Q1
TPS62148RGXR	VQFN-HR	RGX	11	3000	180.0	8.4	2.25	3.25	1.05	4.0	8.0	Q1
TPS62148RGXT	VQFN-HR	RGX	11	250	180.0	8.4	2.25	3.25	1.05	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS
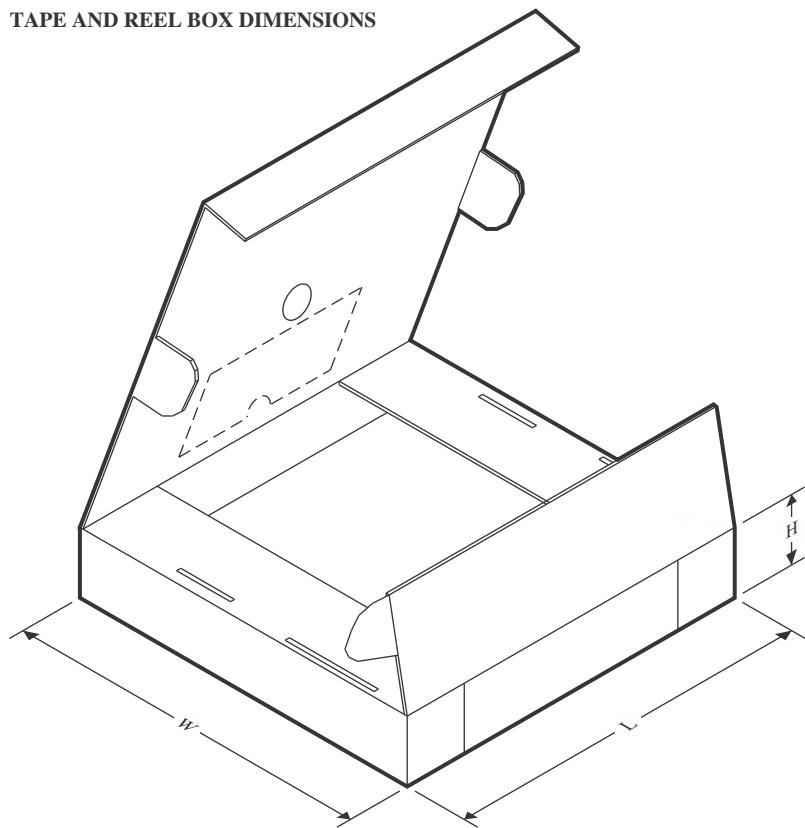
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62147RGXR	VQFN-HR	RGX	11	3000	341.0	182.0	80.0
TPS62147RGXT	VQFN-HR	RGX	11	250	341.0	182.0	80.0
TPS62148RGXR	VQFN-HR	RGX	11	3000	341.0	182.0	80.0
TPS62148RGXT	VQFN-HR	RGX	11	250	341.0	182.0	80.0

B

2.1
1.9

A

PIN 1 INDEX AREA

3.1
2.9

1 MAX

0.05
0.00

C

SEATING PLANE

0.08 C

2X 1.5

6X 0.5

4   7

3X 0.3
0.2

2X 0.5

3

SYMM

1

SYMM

1

PIN 1 ID

8X 0.45
0.35

11   8

SYMM

8X 0.3
0.2

(0.2) TYP

⊕ 0.1 Ⓜ C BⓈ AⓈ
   0.05 Ⓜ C ALL PADS
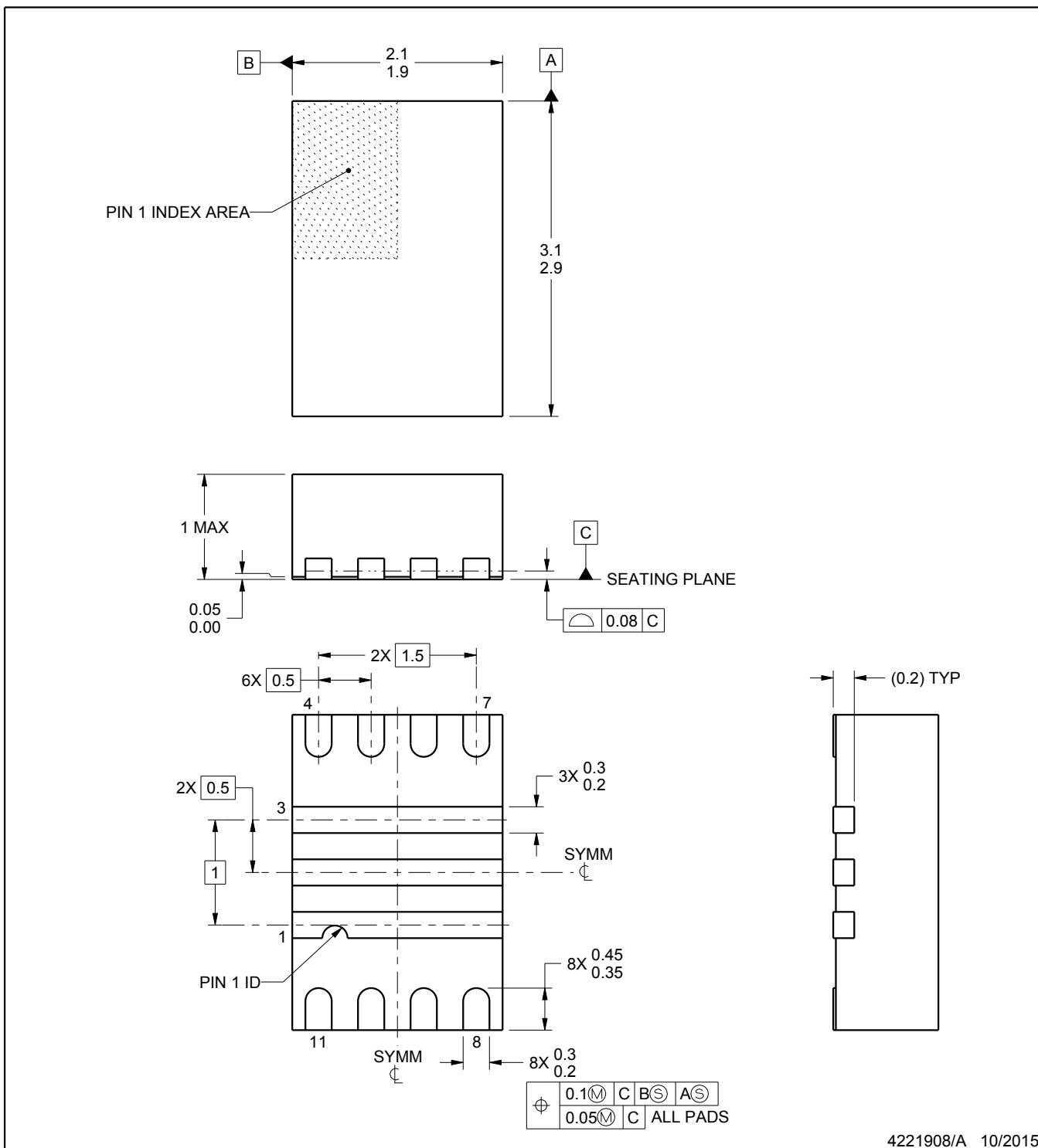
4221908/A   10/2015

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

8X (0.25)

6X (0.5)

11

8

8X (0.6)

1

2X (0.5)

SYMM ℄

(R0.05) TYP

(2.8)

3

3X (0.25)

3X (2.4)

4

7

SYMM ℄

LAND PATTERN EXAMPLE
SCALE:25X

0.05 MAX
ALL AROUND

METAL

0.05 MIN
ALL AROUND

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

NON SOLDER MASK
DEFINED
PADS 4-7 & 8-11

SOLDER MASK
DEFINED
PADS 1-3
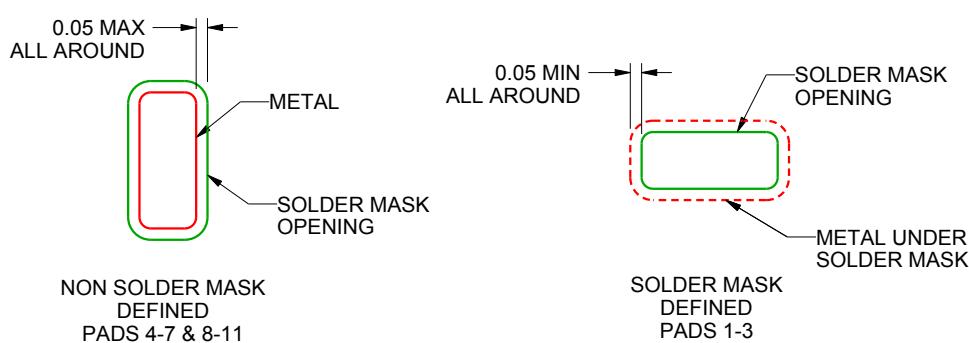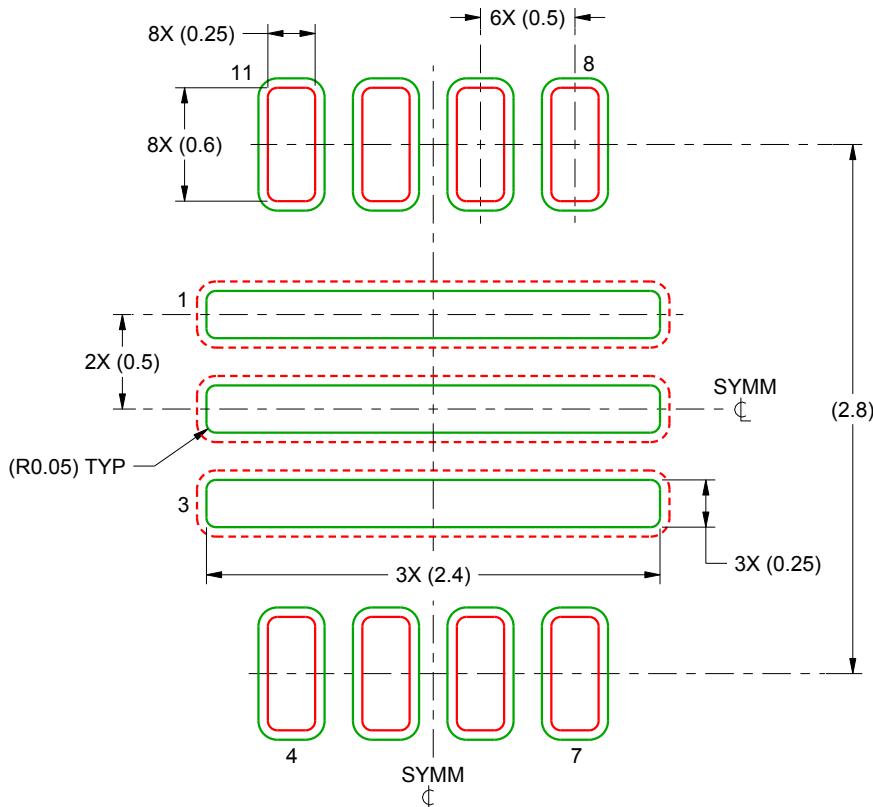
SOLDER MASK DETAILS

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NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
4. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (0.25)

6X (0.5)

11

8

8X (0.6)

6X
EXPOSED METAL

9X (0.66)

9X (0.25)

1

SYMM

(2.8)

(0.5) TYP

3

METAL UNDER
SOLDER MASK
TYP

(0.86) TYP

SOLDER MASK
EDGE, TYP

(R0.05) TYP

4

7

SYMM

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

FOR PADS 1-3
80% PRINTED SOLDER COVERAGE BY AREA
SCALE:30X
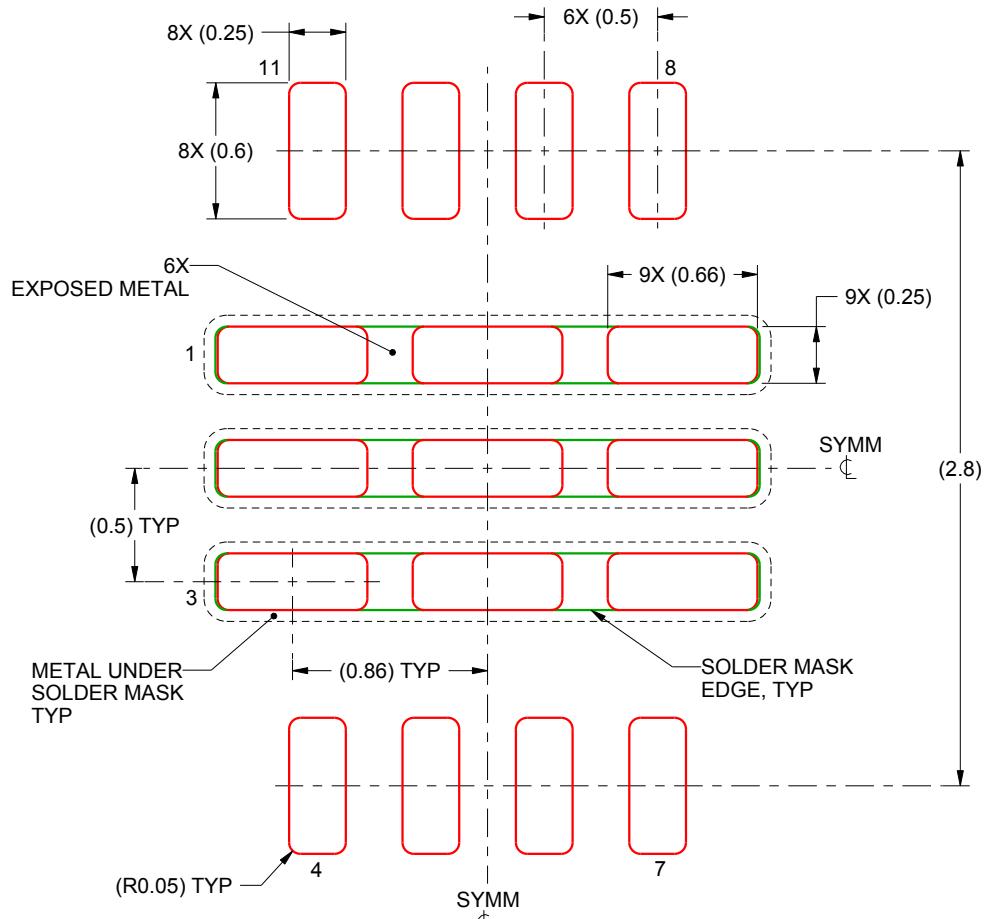
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NOTES: (continued)

5. For alternate stencil design recommendations, see IPC-7525 or board assembly site preference.

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